LM393B, LM2903B, LM193, LM293, LM393 and LM2903 Dual Comparators

1 Features

- NEW LM393B and LM2903B
- Improved specifications of B-version
  - Maximum rating: up to 38V
  - ESD rating (HBM): 2kV
  - Low input offset: 0.37mV
  - Low input bias current: 3.5nA
  - Low supply-current: 200µA per comparator
  - Faster response time of 1µsec
  - Extended temperature range for LM393B
  - Available in tiny 2 x 2mm WSON package
- B-version is drop-in replacement for LM293, LM393 and LM2903, A and V versions
- Common-mode input voltage range includes ground
- Differential input voltage range equal to maximum-rated supply voltage: ±38 V
- Low output saturation voltage
- Output compatible with TTL, MOS, and CMOS

2 Applications

- Vacuum robot
- Single phase UPS
- Server PSU
- Cordless power tool
- Wireless infrastructure
- Applicances
- Building automation
- Factory automation & control
- Motor drives
- Infotainment & cluster

3 Description

The LM393B and LM2903B devices are the next generation versions of the industry-standard LM393 and LM2903 comparator family. These next generation B-version comparators feature lower offset voltage, higher supply voltage capability, lower supply current, lower input bias current, lower propagation delay, and improved 2 kV ESD performance and input ruggedness through dedicated ESD clamps. The LM393B and LM2903B can drop-in replace the LM293, LM393 and LM2903, for both "A" and "V" grades.

All devices consist of two independent voltage comparators that are designed to operate from a single power supply over a wide range of voltages. Quiescent current is independent of the supply voltage.

Device Information

PART NUMBER	PACKAGE(1)	BODY SIZE (NOM)
LM393B, LM2903B, LM193, LM293, LM293A, LM393, LM393A, LM2903, LM2903V, LM2903AV	SOIC (8)	4.90mm x 3.91mm
LM393B, LM2903B, LM293, LM293A, LM393, LM393A, LM2903	VSSOP (8)	3.00mm x 3.00mm
LM293, LM393, LM393A, LM2903	PDIP (8)	9.81mm × 6.35mm
LM393, LM393A, LM2903	SO (8)	6.20mm x 5.30mm
LM393B, LM2903B, LM393, LM393A, LM2903, LM2903V, LM2903AV	TSSOP (8)	3.00mm x 4.40mm
LM393B, LM2903B	SOT-23 (8)	2.90mm x 1.60mm
LM393B, LM2903B	WSON (8)	2.00mm × 2.00mm

(1) For all available packages, see the orderable addendum at the end of the data sheet.

Family Comparison Table

Specification	LM393B	LM2903B	LM393 LM393A	LM2903	LM2903V LM2903AV	LM193	LM293 LM293A	Units
Supply Voltage	2 to 36	2 to 36	2 to 30	2 to 30	2 to 32	2 to 30	2 to 30	V
Total Supply Current (5V to 36V max)	0.6 to 0.8	0.6 to 0.8	1 to 2.5	1 to 2.5	1 to 2.5	1 to 2.5	1 to 2.5	mA
Temperature Range	−40 to 85	−40 to 125	0 to 70	−40 to 125	−40 to 125	−55 to 125	−25 to 85	°C
ESD (HBM)	2000	2000	2000	2000	2000	2000	2000	V
Offset Voltage (Max over temp)	± 4	± 4	± 9 ± 4	± 15	± 15 ± 4	± 9	± 9 ± 4	mV
Input Bias Current (typ / max)	3.5 / 25	3.5 / 25	25 / 250	25 / 250	25 / 250	25 / 100	25 / 250	nA
Response Time (typ)	1	1	1.3	1.3	1.3	1.3	1.3	µsec

An IMPORTANT NOTICE at the end of this data sheet addresses availability, warranty, changes, use in safety-critical applications, intellectual property matters and other important disclaimers. PRODUCTION DATA.

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4 Pin Configuration and Functions

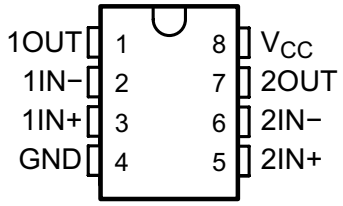
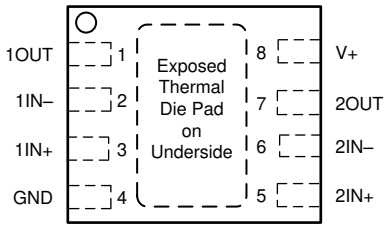


Figure 4-1. D, DGK, JG, P, PS, DDF or PW Package 8-Pin SOIC, VSSOP, PDIP, SO, or TSSOP Top View



Connect thermal pad directly to GND pin.

Figure 4-2. DSG Package 8-Pin WSON With Exposed Pad Top View

Table 4-1. Pin Functions

PIN			I/O	DESCRIPTION
NAME	SOIC, VSSOP, PDIP, SO, DDF and TSSOP	DSG		
1OUT	1	1	Output	Output pin of comparator 1
1IN–	2	2	Input	Negative input pin of comparator 1
1IN+	3	3	Input	Positive input pin of comparator 1
GND	4	4	—	Ground
2IN+	5	5	Input	Positive input pin of comparator 2
2IN-	6	6	Input	Negative input pin of comparator 2
2OUT	7	7	Output	Output pin of comparator 2
V_{CC}	8	8	—	Positive Supply
Thermal Pad	—	PAD	—	Connect directly to GND pin

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5 Specifications

5.1 Absolute Maximum Ratings

over operating free-air temperature range (unless otherwise noted) (1)

			MIN	MAX	UNIT
V_{CC}	Supply voltage(2)	Non-B Versions	–0.3	36	V
		B Versions Only		38	
V_{ID}	Differential input voltage(3)	Non-B Versions	-36	36	V
		B Versions Only	-38	38	
V_I	Input voltage (either input)	Non-B Versions	–0.3	36	V
		B Versions Only		38	
I_{IK}	Input current(5)			-50	mA
V_O	Output voltage	Non-B Versions	–0.3	36	V
		B Versions Only		38	
I_O	Output current	Non-B Versions		20	mA
		B Versions Only		25	
I_{SC}	Duration of output short circuit to ground(4)		Unlimited		
T_J	Operating virtual-junction temperature			150	°C
T_{stg}	Storage temperature		–65	150	°C

(1) Stresses beyond those listed under *Absolute Maximum Ratings* can cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under *Recommended Operating Conditions* is not implied. Exposure to absolute-maximum-rated conditions for extended periods can affect device reliability. Production Processing Does Not Necessarily Include Testing of All Parameters.
(2) All voltage values, except differential voltages, are with respect to network ground.
(3) Differential voltages are at IN+ with respect to IN–.
(4) Short circuits from outputs to V_{CC} can cause excessive heating and eventual destruction.
(5) Input current flows thorough parasitic diode to ground and turns on parasitic transistors that increases I_{CC} and can cause the output to be incorrect. Normal operation resumes when input current is removed.

5.2 Recommended Operating Conditions

Over operating free-air temperature range (unless otherwise noted)

		MIN	MAX	UNIT
Supply voltage, $V_S = (V+) – (V–)$	non-V devices	2	30	V
	V devices	2	32	
	"B" version devices	2	36	
Input voltage range, V_{IVR}	non-B devices	0	(V+) – 2.0	V
	"B" version devices	–0.1		
Ambient temperature, T_A	LM193	–55	125	°C
	LM2903, LM2903V, LM2903AV, LM2903B	–40	125	
	LM393B	–40	85	
	LM293, LM293A	–25	85	
	LM393, LM393A	0	70	

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5.3 Thermal Information: LMx93x and LM2903x

THERMAL METRIC[1]		LMx93x, LM2903x						UNIT
		D (SOIC)	P (PDIP)	PW (TSSOP)	DGK (VSSOP)	DDF (SOT-23)	DSG (WSON)	
		8 PINS	8 PINS	8 PINS	8 PINS	8 PINS	8 PINS	
$R_{\theta JA}$	Junction-to-ambient thermal resistance	148.5	114.9	200.6	193.7	197.9	96.9	°C/W
$R_{\theta JC(top)}$	Junction-to-case (top) thermal resistance	90.2	93.8	89.6	82.9	119.2	119.0	°C/W
$R_{\theta JB}$	Junction-to-board thermal resistance	91.8	77.7	131.3	115.5	115.4	63.1	°C/W
ψ_{JT}	Junction-to-top characterization parameter	38.5	60.4	22.1	20.8	19.4	12.4	°C/W
ψ_{JB}	Junction-to-board characterization parameter	91.1	76.7	129.6	113.9	113.7	63.0	°C/W
$R_{\theta JC(bot)}$	Junction-to-case (bottom) thermal resistance	-	-	-	-	-	37.8	°C/W

(1) For more information about traditional and new thermal metrics, see the *Semiconductor and IC Package Thermal Metrics* report.

5.4 ESD Ratings

			VALUE	UNIT
$V_{(ESD)}$	Electrostatic discharge	Human body model (HBM), per ANSI/ESDA/JEDEC JS-001[1]	±2000	V
		Charged-device model (CDM), per JEDEC specification JESD22-C101[2]	±1000	

(1) JEDEC document JEP155 states that 500V HBM allows safe manufacturing with a standard ESD control process.
(2) JEDEC document JEP157 states that 250V CDM allows safe manufacturing with a standard ESD control process.

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5.5 Electrical Characteristics LM393B

V_S = 5V, V_{CM} = (V–) ; T_A = 25°C (unless otherwise noted).

PARAMETER		TEST CONDITIONS	MIN	TYP	MAX	UNIT
V_{IO}	Input offset voltage	V_S = 5 to 36V	–2.5	±0.37	2.5	mV
		V_S = 5 to 36V, T_A = –40°C to +85°C	-4		4	
	Input offset voltage, DGK package only	V_S = 5 to 36V	–3.5	±0.37	3.5	
		V_S = 5 to 36V, T_A = –40°C to +85°C	–5		5	
I_B	Input bias current			–3.5	–25	nA
		T_A = –40°C to +85°C			–50	nA
I_{OS}	Input offset current		–10	±0.5	10	nA
		T_A = –40°C to +85°C	–25		25	nA
V_{CM}	Common mode range (1)	V_S = 3 to 36V	(V–)		(V+) – 1.5	V
		V_S = 3 to 36V, T_A = –40°C to +85°C	(V–)		(V+) – 2.0	V
A_{VD}	Large signal differential voltage amplification	V_S = 15V, V_O = 1.4V to 11.4V; R_L ≥ 15k to (V+)	50	200		V/mV
V_{OL}	Low level output Voltage {swing from (V–)}	I_{SINK} ≤ 4mA, V_{ID} = -1V		110	400	mV
		I_{SINK} ≤ 4mA, V_{ID} = -1V T_A = –40°C to +85°C			550	mV
I_{OH-LKG}	High-level output leakage current	(V+) = V_O = 5V; V_{ID} = 1V		0.1	20	nA
		(V+) = V_O = 36V; V_{ID} = 1V		0.3	50	nA
I_{OL}	Low level output current	V_{OL} = 1.5V; V_{ID} = -1V; V_S = 5V	6	21		mA
I_Q	Quiescent current (all comparators)	V_S = 5V, no load		400	600	µA
		V_S = 36V, no load, T_A = –40°C to +85°C		550	800	µA

(1) The voltage at either input can not be allowed to go negative by more than 0.3V otherwise output can be incorrect and excessive input current can flow. The upper end of the common-mode voltage range is limited by V_{CC} – 2V. However only one input needs to be in the valid common mode range, the other input can go up the maximum V_{CC} level and the comparator provides a proper output state. Either or both inputs can go to maximum V_{CC} level without damage.

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5.6 Electrical Characteristics LM2903B

V_S = 5V, V_{CM} = (V–) ; T_A = 25°C (unless otherwise noted).

PARAMETER		TEST CONDITIONS	MIN	TYP	MAX	UNIT
V_{IO}	Input offset voltage	V_S = 5 to 36V	–2.5	±0.37	2.5	mV
		V_S = 5 to 36V, T_A = –40°C to +125°C	–4		4	
	Input offset voltage, DGK package only	V_S = 5 to 36V	-3.5	±0.37	3.5	
		V_S = 5 to 36V, T_A = –40°C to +125°C	-5		5	
I_B	Input bias current			–3.5	–25	nA
		T_A = –40°C to +125°C			–50	nA
I_{OS}	Input offset current		–10	±0.5	10	nA
		T_A = –40°C to +125°C	–25		25	nA
V_{CM}	Common mode range (1)	V_S = 3 to 36V	(V–)		(V+) – 1.5	V
		V_S = 3 to 36V, T_A = –40°C to +125°C	(V–)		(V+) – 2.0	V
A_{VD}	Large signal differential voltage amplification	V_S = 15V, V_O = 1.4V to 11.4V; R_L ≥ 15k to (V+)	50	200		V/mV
V_{OL}	Low level output Voltage {swing from (V–)}	I_{SINK} ≤ 4mA, V_{ID} = -1V		110	400	mV
		I_{SINK} ≤ 4mA, V_{ID} = -1V T_A = –40°C to +125°C			550	mV
I_{OH-LKG}	High-level output leakage current	(V+) = V_O = 5V; V_{ID} = 1V		0.1	20	nA
		(V+) = V_O = 36V; V_{ID} = 1V		0.3	50	nA
I_{OL}	Low level output current	V_{OL} = 1.5V; V_{ID} = -1V; V_S = 5V	6	21		mA
I_Q	Quiescent current (all comparators)	V_S = 5V, no load		400	600	µA
		V_S = 36V, no load, T_A = –40°C to +125°C		550	800	µA

(1) The voltage at either input can not be allowed to go negative by more than 0.3V otherwise output can be incorrect and excessive input current can flow. The upper end of the common-mode voltage range is limited by V_{CC} – 2V. However only one input needs to be in the valid common mode range, the other input can go up the maximum V_{CC} level and the comparator provides a proper output state. Either or both inputs can go to maximum V_{CC} level without damage.

5.7 Switching Characteristics LM393B and LM2903B

V_S = 5V, V_{O_PULLUP} = 5V, V_{CM} = V_S/2, C_L = 15pF, R_L = 5.1k Ohm, T_A = 25°C (unless otherwise noted).

PARAMETER		TEST CONDITIONS	MIN	TYP	MAX	UNIT
$t_{response}$	Propagation delay time, high-to-low; TTL input signal (1)	TTL input with V_{ref} = 1.4V		300		ns
$t_{response}$	Propagation delay time, high-to-low; Small scale input signal (1)	Input overdrive = 5mV, Input step = 100mV		1000		ns

(1) High-to-low and low-to-high refers to the transition at the input.

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5.8 Electrical Characteristics for LM193, LM293, and LM393 (without A suffix)

at specified free-air temperature, V_{CC} = 5V (unless otherwise noted)

PARAMETER		TEST CONDITIONS		T_A (1)	LM193			LM293 LM393			UNIT
					MIN	TYP	MAX	MIN	TYP	MAX	
V_{IO}	Input offset voltage	V_{CC} = 5V to 30V, V_{IC} = V_{ICR} min, V_O = 1.4V		25°C		2	5		2	5	mV
				Full range			9			9	
I_{IO}	Input offset current	V_O = 1.4V		25°C		3	25		5	50	nA
				Full range			100			250	
I_{IB}	Input bias current	V_O = 1.4V		25°C		–25	–100		–25	–250	nA
				Full range			–300			–400	
V_{ICR}	Common-mode input-voltage range(2)			25°C	0 to V_{CC} – 1.5			0 to V_{CC} – 1.5			V
				Full range	0 to V_{CC} – 2			0 to V_{CC} – 2			
A_{VD}	Large-signal differential-voltage amplification	V_{CC} = 15V, V_O = 1.4V to 11.4V, R_L ≥ 15kΩ to V_{CC}		25°C	50	200		50	200		V/mV
I_{OH}	High-level output current	V_{OH} = 5V	V_{ID} = 1V	25°C		0.1			0.1	50	nA
		V_{OH} = 30V	V_{ID} = 1V	Full range			1			1	µA
V_{OL}	Low-level output voltage	I_{OL} = 4mA,	V_{ID} = –1V	25°C		150	400		130	400	mV
				Full range			700			700	
I_{OL}	Low-level output current	V_{OL} = 1.5V,	V_{ID} = –1V	25°C	6			6			mA
I_{CC}	Supply current	R_L = ∞	V_{CC} = 5V	25°C		0.8	1		0.45	1	mA
			V_{CC} = 30V	Full range			2.5		0.55	2.5	

(1) Full range (minimum or maximum) for LM193 is –55°C to 125°C, for LM293 is –25°C to 85°C, and for LM393 is 0°C to 70°C. All characteristics are measured with zero common-mode input voltage, unless otherwise specified.

(2) The voltage at either input can not be allowed to go negative by more than 0.3V otherwise output can be incorrect and excessive input current can flow. The upper end of the common-mode voltage range is limited by V_{CC} – 2V. However only one input needs to be in the valid common mode range, and the other input can go up the maximum V_{CC} level and the comparator provides a proper output state. Either or both inputs can go to maximum V_{CC} level without damage.

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5.9 Electrical Characteristics for LM293A and LM393A

at specified free-air temperature, V_{CC} = 5V (unless otherwise noted)

PARAMETER		TEST CONDITIONS		T_A (1)	LM293A LM393A			UNIT
					MIN	TYP	MAX	
V_{IO}	Input offset voltage	V_{CC} = 5V to 30V, V_O = 1.4V V_{IC} = $V_{ICR(min)}$		25°C		1	2	mV
				Full range			4	
I_{IO}	Input offset current	V_O = 1.4V		25°C		5	50	nA
				Full range			150	
I_{IB}	Input bias current	V_O = 1.4V		25°C		–25	–250	nA
				Full range			–400	
V_{ICR}	Common-mode input-voltage range(2)			25°C	0 to V_{CC} – 1.5			V
				Full range	0 to V_{CC} – 2			
A_{VD}	Large-signal differential-voltage amplification	V_{CC} = 15V, V_O = 1.4V to 11.4V, R_L ≥ 15kΩ to V_{CC}		25°C	50	200		V/mV
I_{OH}	High-level output current	V_{OH} = 5V,	V_{ID} = 1V	25°C		0.1	50	nA
		V_{OH} = 30V,	V_{ID} = 1V	Full range			1	µA
V_{OL}	Low-level output voltage	I_{OL} = 4mA,	V_{ID} = –1V	25°C		110	400	mV
				Full range			700	
I_{OL}	Low-level output current	V_{OL} = 1.5V,	V_{ID} = –1V,	25°C	6			mA
I_{CC}	Supply current	R_L = ∞	V_{CC} = 5V	25°C		0.60	1	mA
			V_{CC} = 30V	Full range		0.72	2.5	

(1) Full range (minimum or maximum) for LM293A is –25°C to 85°C, and for LM393A is 0°C to 70°C. All characteristics are measured with zero common-mode input voltage, unless otherwise specified.

(2) The voltage at either input can not be allowed to go negative by more than 0.3V otherwise output can be incorrect and excessive input current can flow. The upper end of the common-mode voltage range is limited by V_{CC} – 2V. However only one input needs to be in the valid common mode range, and the other input can go up the maximum V_{CC} level and the comparator provides a proper output state. Either or both inputs can go to maximum V_{CC} level without damage.

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5.10 Electrical Characteristics for LM2903, LM2903V, and LM2903AV

at specified free-air temperature, V_{CC} = 5V (unless otherwise noted)

PARAMETER		TEST CONDITIONS		T_A (1)	LM2903, LM2903V			LM2903AV			UNIT
					MIN	TYP	MAX	MIN	TYP	MAX	
V_{IO}	Input offset voltage	V_{CC} = 5V to MAX(2) , V_O = 1.4V, V_{IC} = $V_{ICR(min)}$,		25°C		2	7		1	2	mV
				Full range			15			4	
I_{IO}	Input offset current	V_O = 1.4V		25°C		5	50		5	50	nA
				Full range			200			200	
I_{IB}	Input bias current	V_O = 1.4V		25°C		–25	–250		–25	–250	nA
				Full range			–500			–500	
V_{ICR}	Common-mode input-voltage range(3)			25°C	0 to V_{CC} – 1.5			0 to V_{CC} – 1.5			V
				Full range	0 to V_{CC} – 2			0 to V_{CC} – 2			
A_{VD}	Large-signal differential-voltage amplification	V_{CC} = 15V, V_O = 1.4V to 11.4V, R_L ≥ 15kΩ to V_{CC}		25°C	25	100		25	100		V/mV
I_{OH}	High-level output current	V_{OH} = 5V,	V_{ID} = 1V	25°C		0.1	50		0.1	50	nA
		V_{OH} = V_{CC} MAX(2),	V_{ID} = 1V	Full range			1			1	µA
V_{OL}	Low-level output voltage	I_{OL} = 4mA,	V_{ID} = –1V,	25°C		150	400		150	400	mV
				Full range			700			700	
I_{OL}	Low-level output current	V_{OL} = 1.5V,	V_{ID} = –1V	25°C	6			6			mA
I_{CC}	Supply current	R_L = ∞	V_{CC} = 5V	25°C		0.8	1		0.8	1	mA
			V_{CC} = MAX	Full range			2.5			2.5	

(1) Full range (minimum or maximum) for LM2903 is –40°C to 125°C. All characteristics are measured with zero common-mode input voltage, unless otherwise specified.
(2) V_{CC} MAX = 30V for non-V devices and 32V for V-suffix devices.
(3) The voltage at either input can not be allowed to go negative by more than 0.3V otherwise output can be incorrect and excessive input current can flow. The upper end of the common-mode voltage range is limited by V_{CC} – 2V. However only one input needs to be in the valid common mode range, the other input can go up the maximum V_{CC} level and the comparator provides a proper output state. Either or both inputs can go to maximum V_{CC} level without damage.

5.11 Switching Characteristics: LM193, LM239, LM393, LM2903, all 'A' and 'V' versions

V_{CC} = 5V, T_A = 25°C

PARAMETER	TEST CONDITIONS		TYP	UNIT
Response time	R_L connected to 5V through 5.1kΩ, C_L = 15pF(1) (2)	100mV input step with 5mV overdrive	1.3	µs
		TTL-level input step	0.3	

(1) C_L includes probe and jig capacitance.
(2) The response time specified is the interval between the input step function and the instant when the output crosses 1.4V.

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5.12 Typical Characteristics, LMx93x and LM2903x

T_A = 25°C, V_S = 5V, R_{PULLUP} = 5.1k, C_L = 15pF, V_{CM} = 0V, $V_{UNDERDRIVE}$ = 100mV, $V_{OVERDRIVE}$ = 100mV unless otherwise noted.

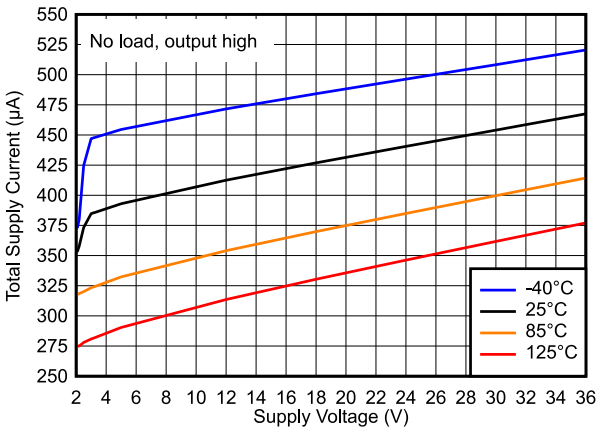

Figure 5-1. Total Supply Current vs. Supply Voltage

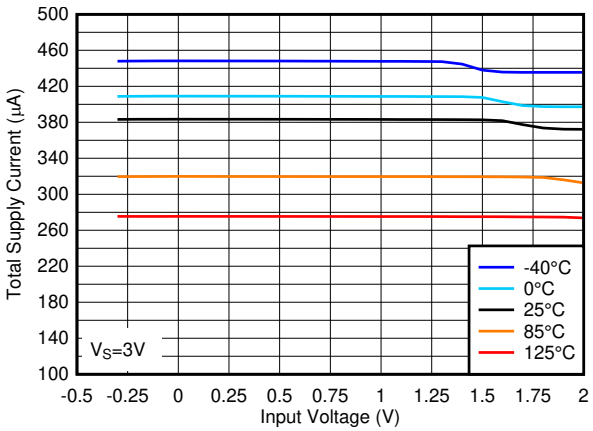

Figure 5-2. Total Supply Current vs. Input Voltage at 3V

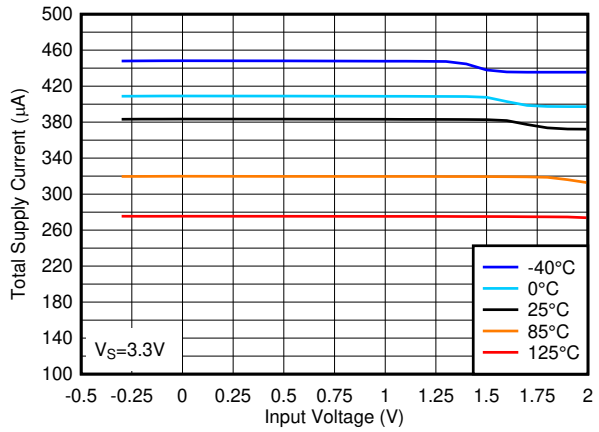

Figure 5-3. Total Supply Current vs. Input Voltage at 3.3V

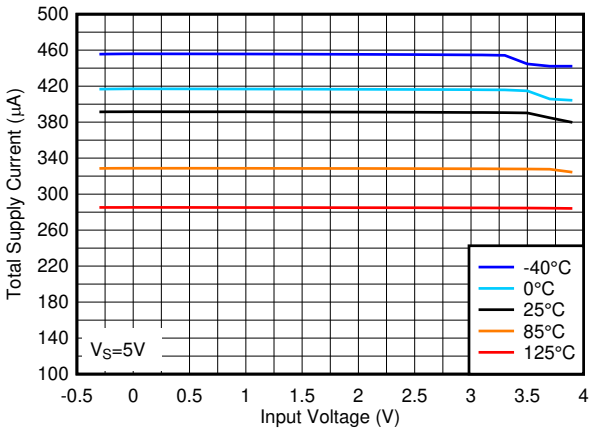

Figure 5-4. Total Supply Current vs. Input Voltage at 5V

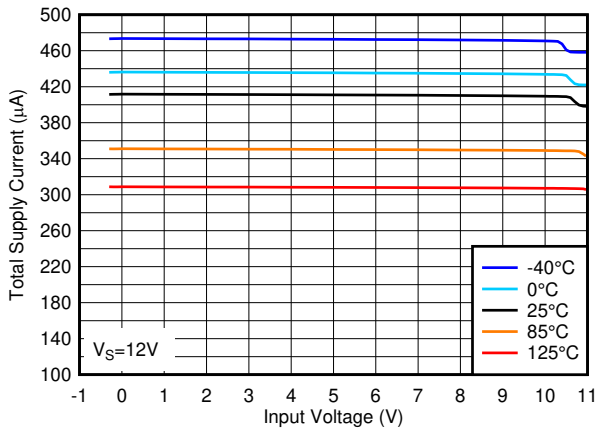

Figure 5-5. Total Supply Current vs. Input Voltage at 12V

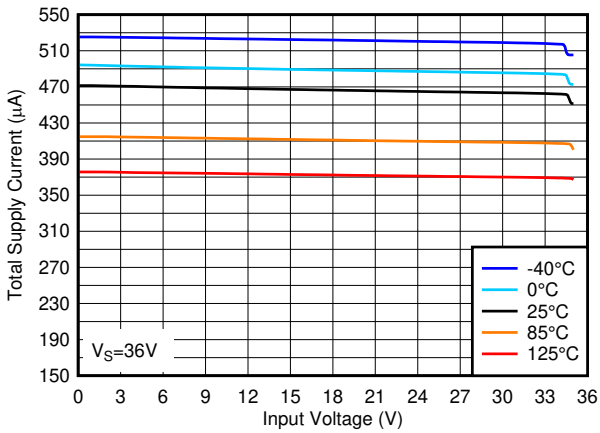

Figure 5-6. Total Supply Current vs. Input Voltage at 36V

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5.12 Typical Characteristics, LMx93x and LM2903x (continued)

T_A = 25°C, V_S = 5V, R_{PULLUP} = 5.1k, C_L = 15pF, V_{CM} = 0V, $V_{UNDERDRIVE}$ = 100mV, $V_{OVERDRIVE}$ = 100mV unless otherwise noted.

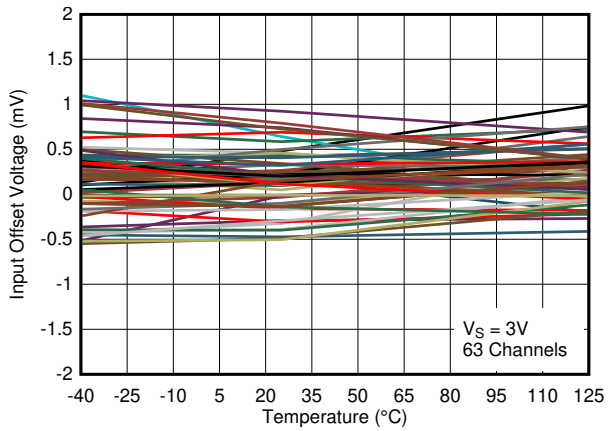

Figure 5-7. Input Offset Voltage vs. Temperature at 3V

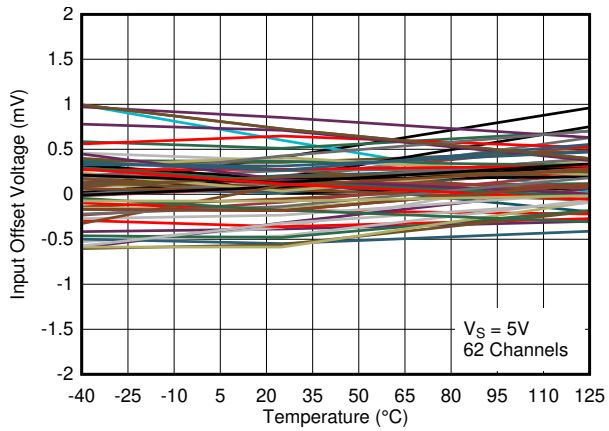

Figure 5-8. Input Offset Voltage vs. Temperature at 5V

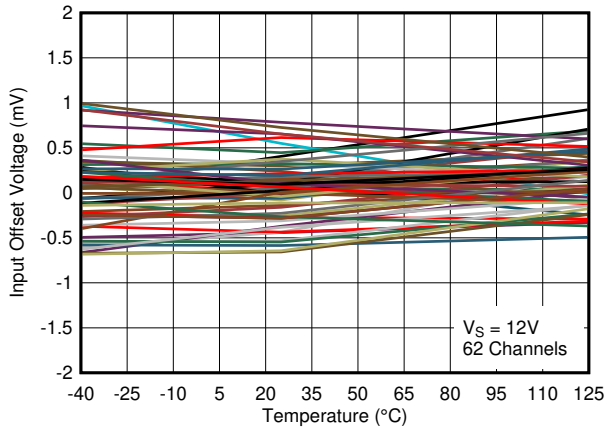

Figure 5-9. Input Offset Voltage vs. Temperature at 12V

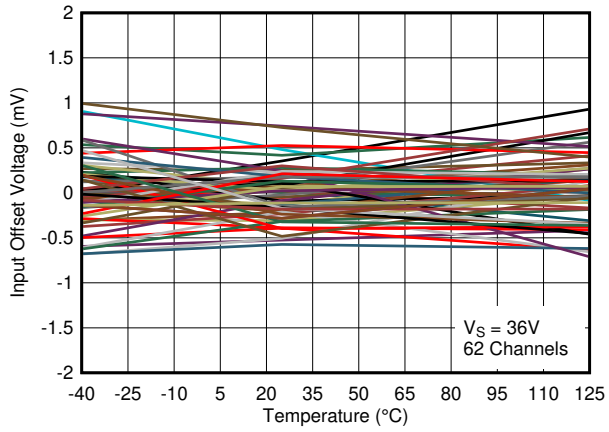

Figure 5-10. Input Offset Voltage vs. Temperature at 36

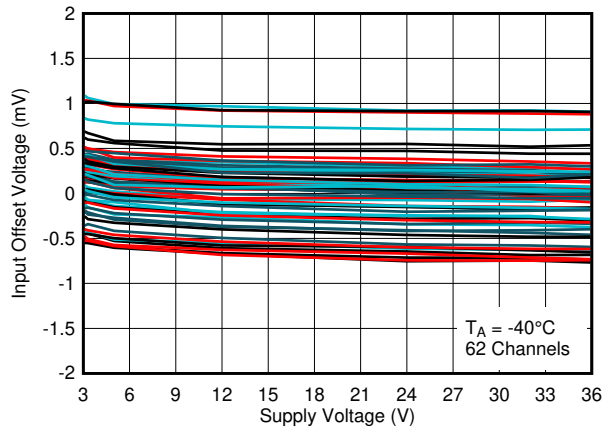

Figure 5-11. Input Offset Voltage vs. Supply Voltage at -40°C

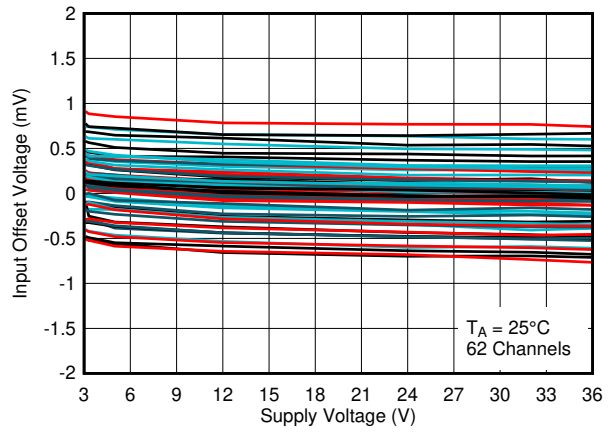

Figure 5-12. Input Offset Voltage vs. Supply Voltage at 25°C

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5.12 Typical Characteristics, LMx93x and LM2903x (continued)

T_A = 25°C, V_S = 5V, R_{PULLUP} = 5.1k, C_L = 15pF, V_{CM} = 0V, $V_{UNDERDRIVE}$ = 100mV, $V_{OVERDRIVE}$ = 100mV unless otherwise noted.

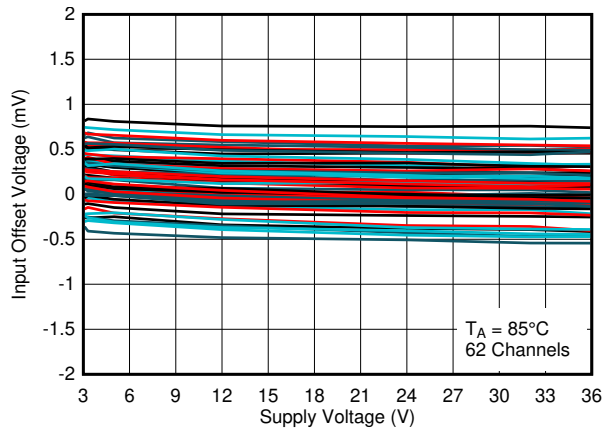

Figure 5-13. Input Offset Voltage vs. Supply Voltage at 85°C

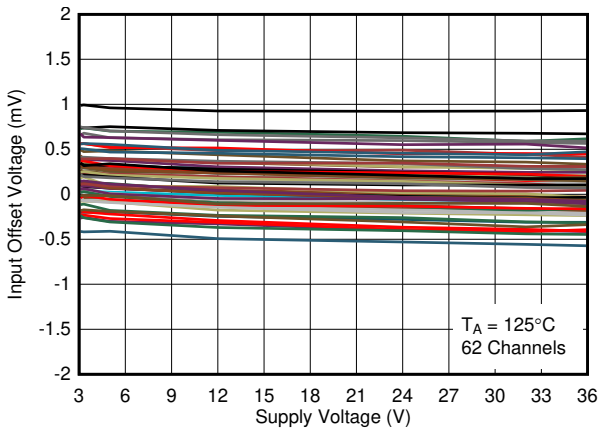

Figure 5-14. Input Offset Voltage vs. Supply Voltage at 125°C

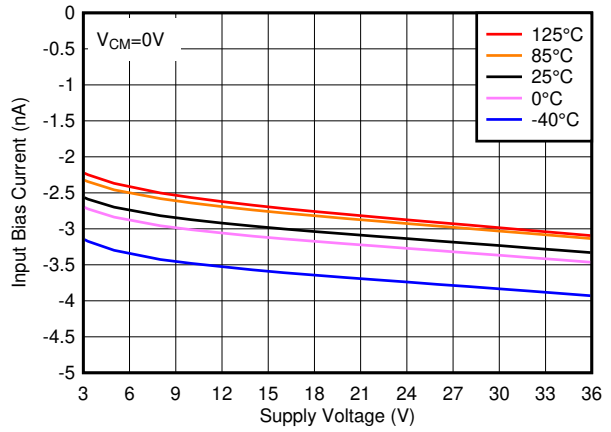

Figure 5-15. Input Bias Current vs. Supply Voltage

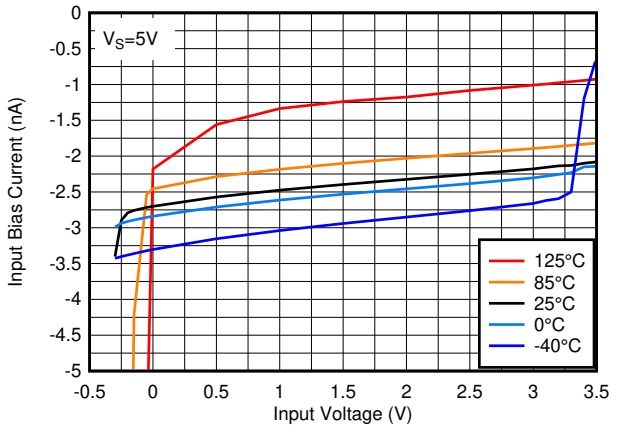

Figure 5-16. Input Bias Current vs. Input Voltage at 5V

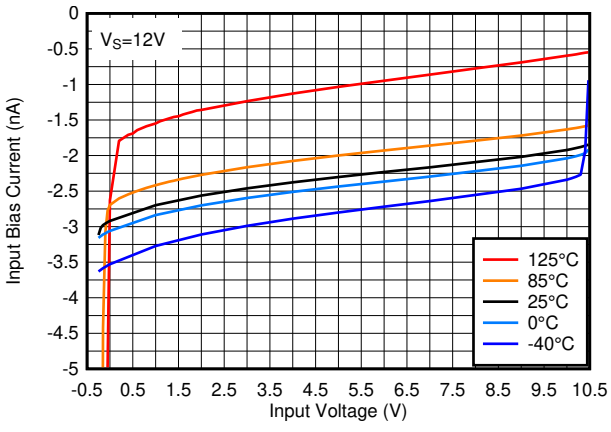

Figure 5-17. Input Bias Current vs. Input Voltage at 12V

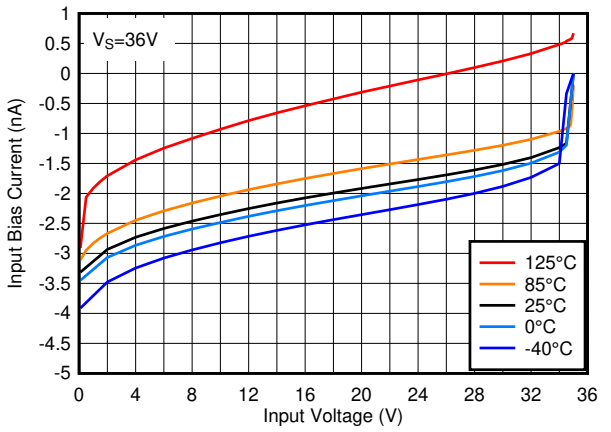

Figure 5-18. Input Bias Current vs. Input Voltage at 36V

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5.12 Typical Characteristics, LMx93x and LM2903x (continued)

T_A = 25°C, V_S = 5V, R_{PULLUP} = 5.1k, C_L = 15pF, V_{CM} = 0V, $V_{UNDERDRIVE}$ = 100mV, $V_{OVERDRIVE}$ = 100mV unless otherwise noted.

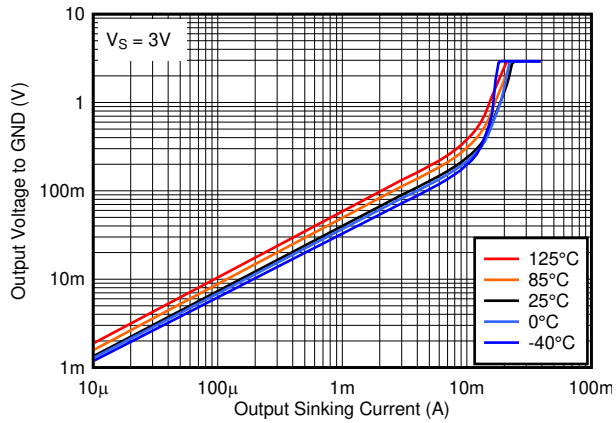

Figure 5-19. Output Low Voltage vs. Output Sinking Current at 3V

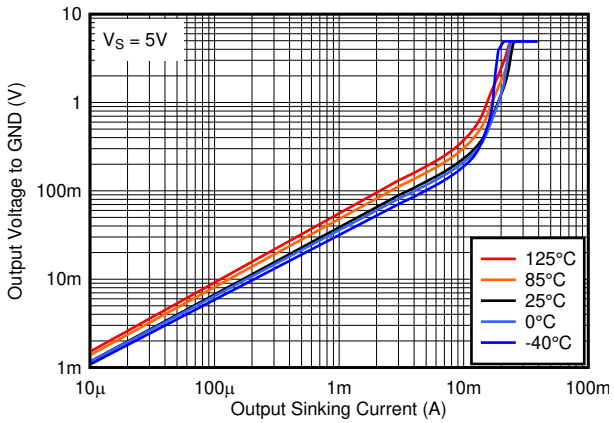

Figure 5-20. Output Low Voltage vs. Output Sinking Current at 5V

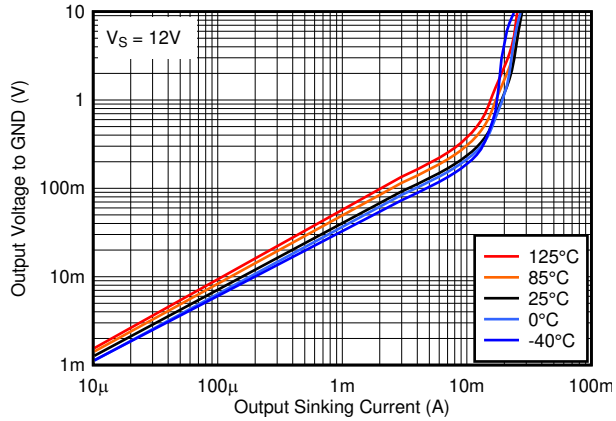

Figure 5-21. Output Low Voltage vs. Output Sinking Current at 12V

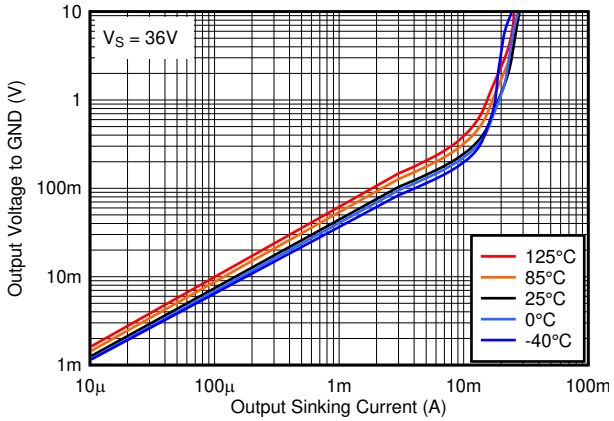

Figure 5-22. Output Low Voltage vs.Output Sinking Current at 36V

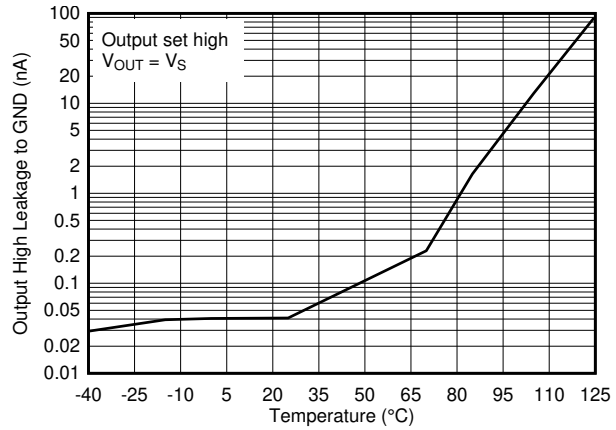

Figure 5-23. Output High Leakage Current vs.Temperature at 5V

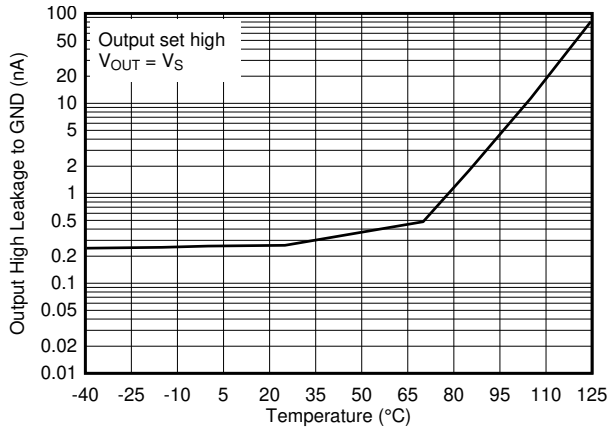

Figure 5-24. Output High Leakage Current vs. Temperature at 36V

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5.12 Typical Characteristics, LMx93x and LM2903x (continued)

T_A = 25°C, V_S = 5V, R_{PULLUP} = 5.1k, C_L = 15pF, V_{CM} = 0V, $V_{UNDERDRIVE}$ = 100mV, $V_{OVERDRIVE}$ = 100mV unless otherwise noted.

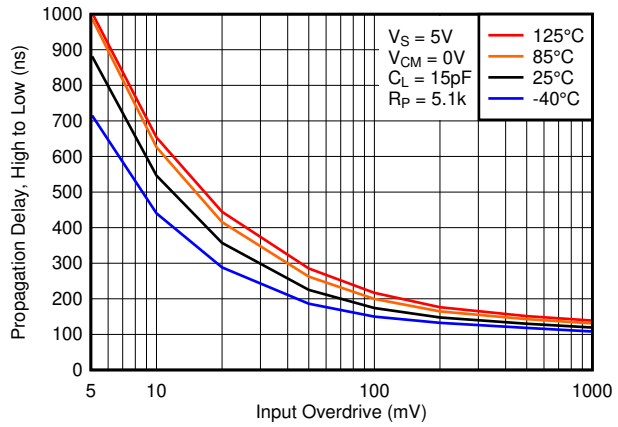

Figure 5-25. High to Low Propagation Delay vs. Input Overdrive Voltage, 5V

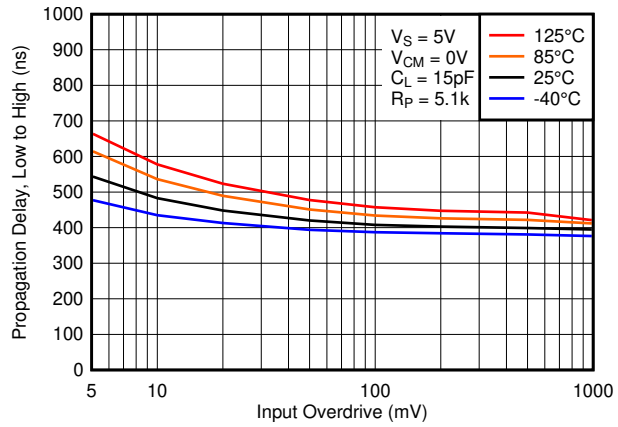

Figure 5-26. Low to High Propagation Delay vs. Input Overdrive Voltage, 5V

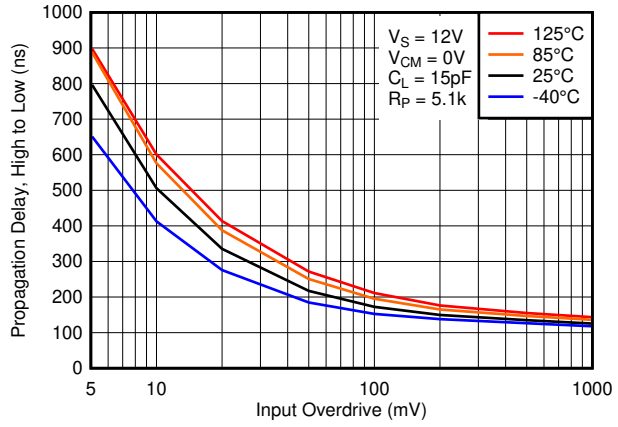

Figure 5-27. High to Low Propagation Delay vs. Input Overdrive Voltage, 12V

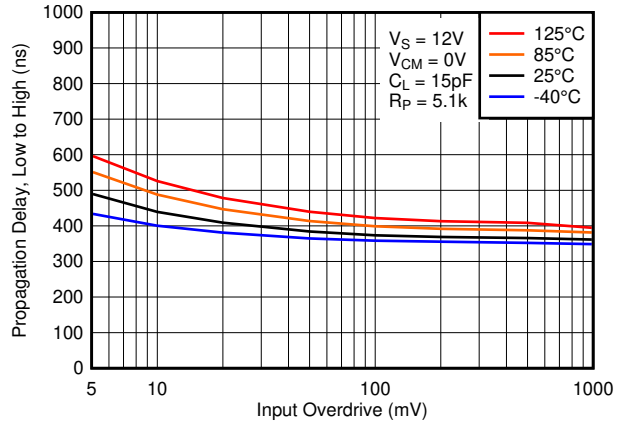

Figure 5-28. Low to High Propagation Delay vs. Input Overdrive Voltage, 12V

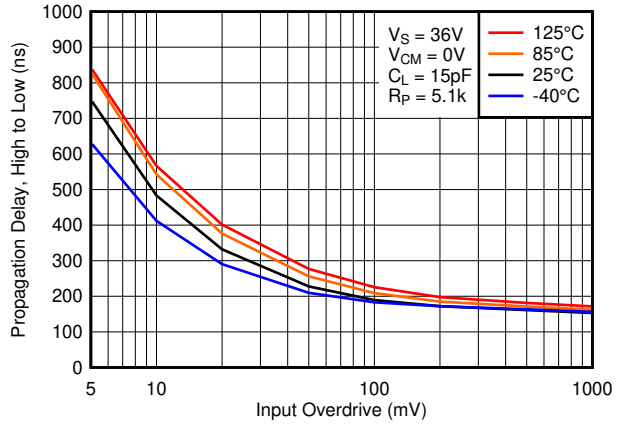

Figure 5-29. High to Low Propagation Delay vs. Input Overdrive Voltage, 36V

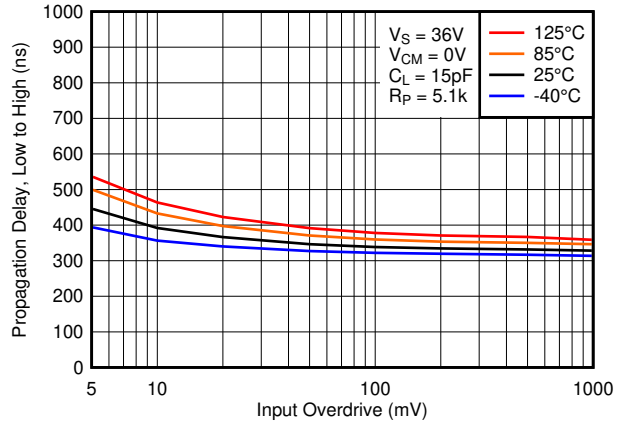

Figure 5-30. Low to High Propagation Delay vs. Input Overdrive Voltage, 36V

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5.12 Typical Characteristics, LMx93x and LM2903x (continued)

T_A = 25°C, V_S = 5V, R_{PULLUP} = 5.1k, C_L = 15pF, V_{CM} = 0V, $V_{UNDERDRIVE}$ = 100mV, $V_{OVERDRIVE}$ = 100mV unless otherwise noted.

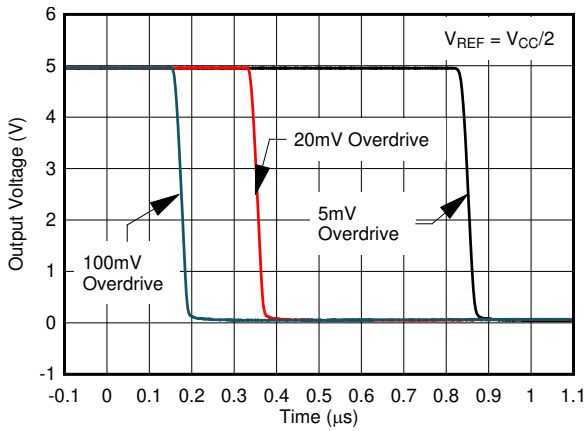

Figure 5-31. Response Time for Various Overdrives, High-to-Low Transition

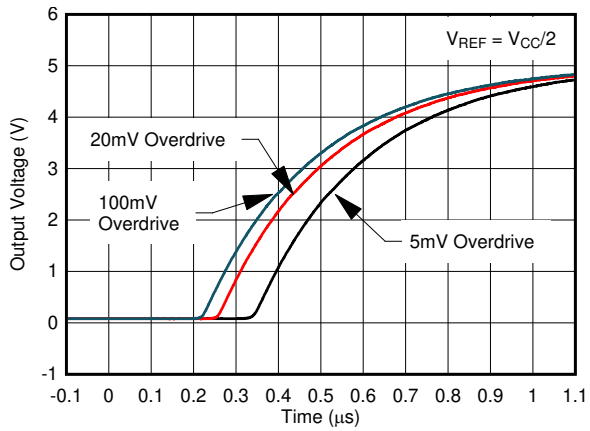

Figure 5-32. Response Time for Various Overdrives, Low-to-High Transition

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6 Detailed Description

6.1 Overview

These dual comparators have the ability to operate up to absolute maximum of 36V (38V for the "B" version) on the supply pin. This device has proven ubiquity and versatility across a wide range of applications. This is due to very wide supply voltages range, low Iq and fast response of the devices.

The open-collector outputs allow the user to level shift to the desired logic level indpendent of VCC, while also enabling AND functionality when multiple outputs are connected together.

6.2 Functional Block Diagram

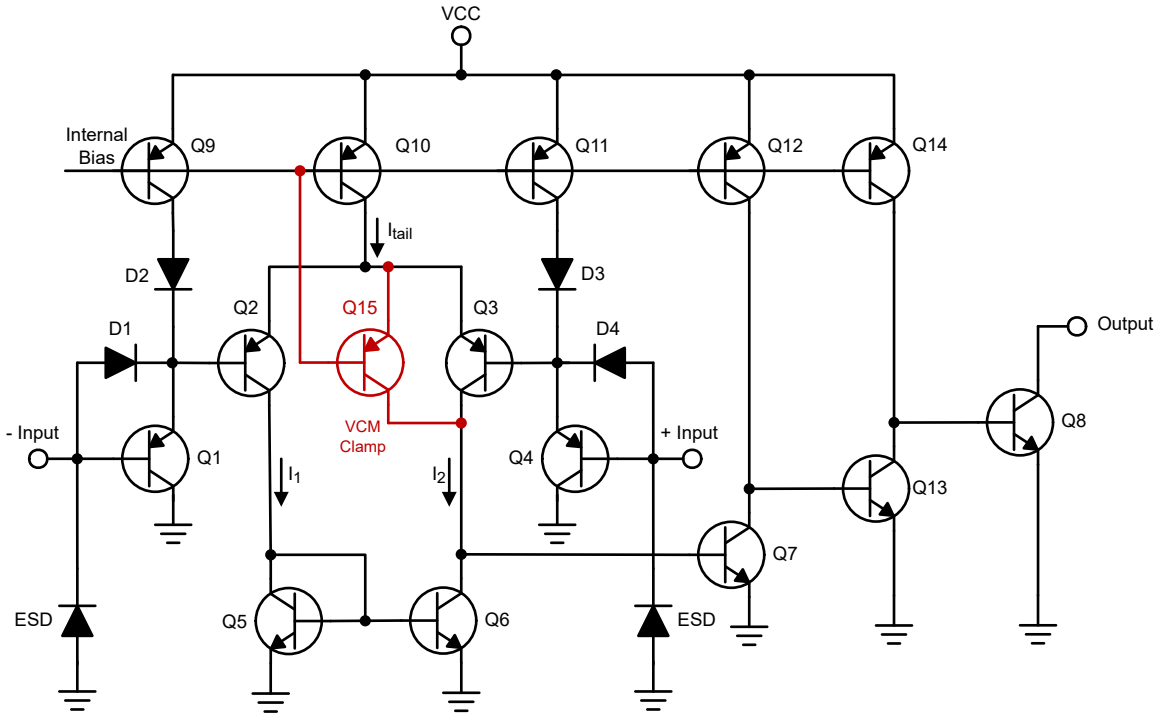

Figure 6-1. Schematic (Each Comparator)

6.3 Feature Description

The comparator consists of a PNP Darlington pair input, allowing the device to operate with very high gain and fast response with minimal input bias current. The input Darlington pair creates a limit on the input common mode voltage capability, allowing the comparator to accurately function from ground to V_{CC}– 2V over temperature. A clamp is added around Q3 to mimic the both inputs above input voltage range behavior of the original classic silicon.

The output consists of an open drain NPN (pull-down or low side) transistor. The output NPN sinks current when the negative input voltage is higher than the positive input voltage and the offset voltage. The V_{OL} is resistive and scales with the output current. Please see the "Output Low Voltage vs. Output Sinking Current" graphs for V_{OL} values with respect to the output current.

6.4 Device Functional Modes

6.4.1 Voltage Comparison

The device operates solely as a voltage comparator, comparing the differential voltage between the positive and negative pins and outputting a logic low or high impedance (logic high with pullup) based on the input differential polarity.

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7 Application and Implementation

Note

Information in the following applications sections is not part of the TI component specification, and TI does not warrant its accuracy or completeness. TI's customers are responsible for determining suitability of components for their purposes, as well as validating and testing their design implementation to confirm system functionality.

7.1 Application Information

The device is typically used to compare a single signal to a reference or two signals against each other. Many users take advantage of the open drain output to drive the comparison logic output to a logic voltage level to an MCU or logic device. The wide supply range and high voltage capability makes this comaprator an excellent choice for level shifting to a higher or lower voltage.

7.2 Typical Application

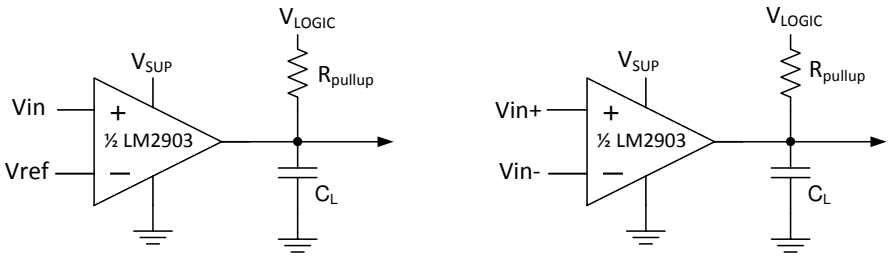

Figure 7-1. Single-Ended and Differential Comparator Configurations

7.2.1 Design Requirements

For this design example, use the parameters listed in Table 7-1 as the input parameters.

Table 7-1. Design Parameters

DESIGN PARAMETER	EXAMPLE VALUE
Input Voltage Range	0V to Vsup-2V
Supply Voltage	4.5V to V_{CC} maximum
Logic Supply Voltage	0V to V_{CC} maximum
Output Current (R_{PULLUP})	1µA to 4mA
Input Overdrive Voltage	100mV
Reference Voltage	2.5V
Load Capacitance (C_L)	15pF

7.2.2 Detailed Design Procedure

When using the device in a general comparator application, determine the following:

- Input Voltage Range
- Minimum Overdrive Voltage
- Output and Drive Current
- Response Time

7.2.2.1 Input Voltage Range

When choosing the input voltage range, the input common mode voltage range (V_{ICR}) must be taken in to account. If temperature operation is below 25°C the V_{ICR} can range from 0V to V_{CC}– 2.0V. This limits the input

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voltage range to as high as V_{CC}– 2.0V and as low as 0V. Operation outside of this range can yield incorrect comparisons.

The following is a list of input voltage situation and the outcomes:

1. When both IN- and IN+ are both within the common-mode range:
   a. If IN- is higher than IN+ and the offset voltage, the output is low and the output transistor is sinking current
   b. If IN- is lower than IN+ and the offset voltage, the output is high impedance and the output transistor is not conducting
2. When IN- is higher than common-mode and IN+ is within common-mode, the output is low and the output transistor is sinking current
3. When IN+ is higher than common-mode and IN- is within common-mode, the output is high impedance and the output transistor is not conducting
4. When IN- and IN+ are both higher than common-mode, see Section 2 of Application Design Guidelines for LM339, LM393, TL331 Family Comparators Including the New B-versions.

7.2.2.2 Minimum Overdrive Voltage

Overdrive Voltage is the differential voltage produced between the positive and negative inputs of the comparator over the offset voltage (V_{IO}). To make an accurate comparison the Overdrive Voltage (V_{OD}) must be higher than the input offset voltage (V_{IO}). Overdrive voltage can also determine the response time of the comparator, with the response time decreasing with increasing overdrive. Figure 7-2 and Figure 7-3 show positive and negative response times with respect to overdrive voltage.

7.2.2.3 Output and Drive Current

Output current is determined by the load/pull-up resistance and logic/pullup voltage. The output current produces a output low voltage (V_{OL}) from the comparator. In which V_{OL} is proportional to the output current. See the *Output Low vs. Sinking Current* graphs in the *Typical Characteristics, LMx93x and LM2903x* section to determine V_{OL} based on the output current.

The output current can also effect the transient response. See *Section 7.2.2.4* for more information.

7.2.2.4 Response Time

Response time is a function of input over drive. See *Application Curves* for typical response times. The rise and falls times can be determined by the load capacitance (C_L), load/pullup resistance (R_{PULLUP}) and equivalent collector-emitter resistance (R_{CE}).

- The rise time (τ_R) is approximately $\tau_R = R_{PULLUP} \times C_L$
- The fall time (τ_F) is approximately $\tau_F = R_{CE} \times C_L$
  – R_{CE} can be determine by taking the slope of *Figure 5-20* in the linear region at the desired temperature, or by dividing the V_{OL} by I_{out}

7.2.3 Application Curves

The following curves are generated with 5V on V_{CC} and V_{Logic}, R_{PULLUP} = 5.1kΩ, and 50pF scope probe.

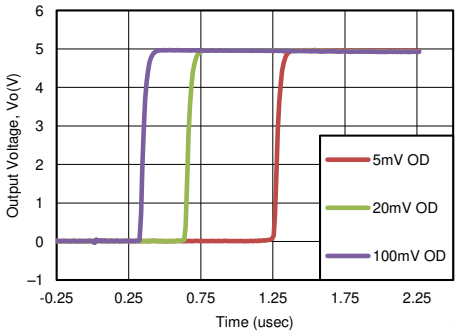

Figure 7-2. Response Time for Various Overdrives (Positive Transition)

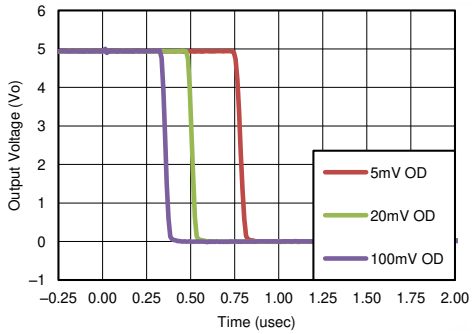

Figure 7-3. Response Time for Various Overdrives (Negative Transition)

7.2.4 Power Supply Recommendations

For fast response and comparison applications with noisy or AC inputs, TI recommends to use a bypass capacitor on the supply pin to reject any variation on the supply voltage. This variation can eat into the input common-mode range of the comparator and create an inaccurate comparison.

7.2.5 Layout

7.2.5.1 Layout Guidelines

For accurate comparator applications without hysteresis maintaining a stable power supply with minimized noise and glitches is critical. Best practice is to add a bypass capacitor between the supply voltage and ground. This can be implemented on the positive power supply and negative supply (if available). If a negative supply is not being used, do not put a capacitor between the IC's GND pin and system ground.

Minimize coupling between outputs and inverting inputs to prevent output oscillations. Do not run output and inverting input traces in parallel unless there is a V_{CC} or GND trace between output and inverting input traces to reduce coupling. When series resistance is added to inputs, place resistor close to the device.

7.2.5.2 Layout Example

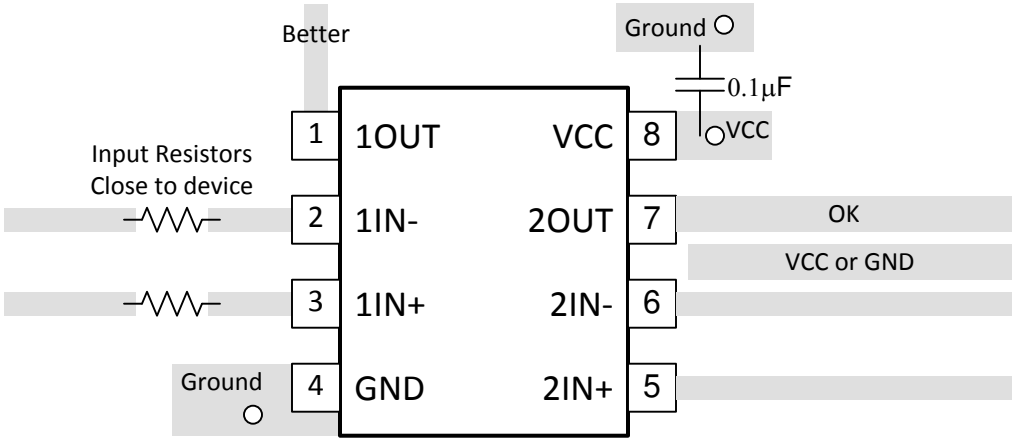

Figure 7-4. LM2903 Layout Example

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8 Device and Documentation Support

8.1 Receiving Notification of Documentation Updates

To receive notification of documentation updates, navigate to the device product folder on ti.com. Click on *Notifications* to register and receive a weekly digest of any product information that has changed. For change details, review the revision history included in any revised document.

8.2 Support Resources

TI E2E™ support forums are an engineer's go-to source for fast, verified answers and design help — straight from the experts. Search existing answers or ask your own question to get the quick design help you need.

Linked content is provided "AS IS" by the respective contributors. They do not constitute TI specifications and do not necessarily reflect TI's views; see TI's Terms of Use.

8.3 Trademarks

TI E2E™ is a trademark of Texas Instruments.
All trademarks are the property of their respective owners.

8.4 Electrostatic Discharge Caution

This integrated circuit can be damaged by ESD. Texas Instruments recommends that all integrated circuits be handled with appropriate precautions. Failure to observe proper handling and installation procedures can cause damage.

ESD damage can range from subtle performance degradation to complete device failure. Precision integrated circuits may be more susceptible to damage because very small parametric changes could cause the device not to meet its published specifications.

8.5 Glossary

TI Glossary	This glossary lists and explains terms, acronyms, and definitions.

9 Revision History

NOTE: Page numbers for previous revisions may differ from page numbers in the current version.

Changes from Revision AG (January 2025) to Revision AH (April 2025)	Page
• Updated front page *Family Comparison Table* ESD specs	1
• Restored missing "P" package column in *Thermal Information* table	5

Changes from Revision AF (August 2023) to Revision AG (January 2025)	Page
• Removed legacy device graphs	11
• Updated internal *Schematic*	17

Changes from Revision AE (November 2020) to Revision AF (August 2023)	Page
• Added reference to Application Note	18

Changes from Revision AD (October 2020) to Revision AE (November 2020)	Page
• Corrected Family Comparison Table Offset Voltage units to mV	1
• LM393B and LM2903B recommended minimum supply votlage changed to 2V throughout	1
• Added separate offset voltage row for LM393B and LM2903B DGK package	1
• Changed "B" devices recommended minimum supply votlage to 2V	4

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- Updated "B" device Supply Current vs Supply Voltage Graph for 2V....11

Changes from Revision AC (February 2020) to Revision AD (October 2020) **Page**

- Updated the numbering format for tables, figures and cross-references throughout the document.... 1

Changes from Revision AB (December 2019) to Revision AC (February 2020) **Page**

- Changed front page Features, Applications and Description text to highlight B version....1
- Added WSON and SOT-23-8 packages....1
- Added Links to Family Table 1
- Added DDF and DSG pkgs to Thermal Table....5

Changes from Revision AA (September 2019) to Revision AB (December 2019) **Page**

- Changed LM393B and LM2903B from Preview to Active status....1
- Added Family Comparison Table....1

Changes from Revision Z (October 2017) to Revision AA (September 2019) **Page**

- Added "B" devices with various text changes throughout data sheet....1
- Deleted from Device Information old LM193 CDIP and LCCC package references and drawings. These are on the LM139-MIL data sheet....1
- Added "B" devices Thermal Information table....5
- Added "B" device electrical tables....5
- Added "B" device graphs 11

10 Mechanical, Packaging, and Orderable Information

The following pages include mechanical, packaging, and orderable information. This information is the most current data available for the designated devices. This data is subject to change without notice and revision of this document. For browser based versions of this data sheet, refer to the left hand navigation.

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PACKAGING INFORMATION

Orderable part number	Status (1)	Material type (2)	Package | Pins	Package qty | Carrier	RoHS (3)	Lead finish/ Ball material (4)	MSL rating/ Peak reflow (5)	Op temp (°C)	Part marking (6)
LM193DR	Active	Production	SOIC (D) | 8	2500 | LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-55 to 125	LM193
LM193DR.A	Active	Production	SOIC (D) | 8	2500 | LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-55 to 125	LM193
LM193DRG4	Active	Production	SOIC (D) | 8	2500 | LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-55 to 125	LM193
LM193DRG4.A	Active	Production	SOIC (D) | 8	2500 | LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-55 to 125	LM193
LM2903AVQDR	Active	Production	SOIC (D) | 8	2500 | LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	L2903AV
LM2903AVQDR.A	Active	Production	SOIC (D) | 8	2500 | LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	L2903AV
LM2903AVQDRG4	Active	Production	SOIC (D) | 8	2500 | LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	L2903AV
LM2903AVQDRG4.A	Active	Production	SOIC (D) | 8	2500 | LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	L2903AV
LM2903AVQPWR	Active	Production	TSSOP (PW) | 8	2000 | LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	(2903AV, L2903AV)
LM2903AVQPWR.A	Active	Production	TSSOP (PW) | 8	2000 | LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	(2903AV, L2903AV)
LM2903AVQPWR.B	Active	Production	TSSOP (PW) | 8	2000 | LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	(2903AV, L2903AV)
LM2903AVQPWRG4	Active	Production	TSSOP (PW) | 8	2000 | LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	(2903AV, L2903AV)
LM2903AVQPWRG4.A	Active	Production	TSSOP (PW) | 8	2000 | LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	(2903AV, L2903AV)
LM2903AVQPWRG4.B	Active	Production	TSSOP (PW) | 8	2000 | LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	(2903AV, L2903AV)
LM2903BIDDFR	Active	Production	SOT-23-THIN (DDF) | 8	3000 | LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	2903B
LM2903BIDDFR.B	Active	Production	SOT-23-THIN (DDF) | 8	3000 | LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	2903B
LM2903BIDDFRG4	Active	Production	SOT-23-THIN (DDF) | 8	3000 | LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	2903B
LM2903BIDDFRG4.B	Active	Production	SOT-23-THIN (DDF) | 8	3000 | LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	2903B
LM2903BIDGKR	Active	Production	VSSOP (DGK) | 8	2500 | LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	903B
LM2903BIDGKR.A	Active	Production	VSSOP (DGK) | 8	2500 | LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	903B
LM2903BIDGKR.B	Active	Production	VSSOP (DGK) | 8	2500 | LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	903B
LM2903BIDGKRG4	Active	Production	VSSOP (DGK) | 8	2500 | LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	903B
LM2903BIDGKRG4.A	Active	Production	VSSOP (DGK) | 8	2500 | LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	903B
LM2903BIDGKRG4.B	Active	Production	VSSOP (DGK) | 8	2500 | LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	903B
LM2903BIDR	Active	Production	SOIC (D) | 8	2500 | LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	L2903B
LM2903BIDR.A	Active	Production	SOIC (D) | 8	2500 | LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	L2903B
LM2903BIDR.B	Active	Production	SOIC (D) | 8	2500 | LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	L2903B
LM2903BIDRG4	Active	Production	SOIC (D) | 8	2500 | LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	L2903B
LM2903BIDRG4.A	Active	Production	SOIC (D) | 8	2500 | LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	L2903B

Orderable part number	Status (1)	Material type (2)	Package | Pins	Package qty | Carrier	RoHS (3)	Lead finish/ Ball material (4)	MSL rating/ Peak reflow (5)	Op temp (°C)	Part marking (6)
LM2903BIDRG4.B	Active	Production	SOIC (D) | 8	2500 | LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	L2903B
LM2903BIDSGR	Active	Production	WSON (DSG) | 8	3000 | LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	903B
LM2903BIDSGR.A	Active	Production	WSON (DSG) | 8	3000 | LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	903B
LM2903BIDSGR.B	Active	Production	WSON (DSG) | 8	3000 | LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	903B
LM2903BIDSGRG4	Active	Production	WSON (DSG) | 8	3000 | LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	903B
LM2903BIDSGRG4.A	Active	Production	WSON (DSG) | 8	3000 | LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	903B
LM2903BIDSGRG4.B	Active	Production	WSON (DSG) | 8	3000 | LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	903B
LM2903BIPWR	Active	Production	TSSOP (PW) | 8	2000 | LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	L2903B
LM2903BIPWR.B	Active	Production	TSSOP (PW) | 8	2000 | LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	L2903B
LM2903DGKR	Active	Production	VSSOP (DGK) | 8	2500 | LARGE T&R	Yes	NIPDAU | SN | NIPDAUAG	Level-1-260C-UNLIM	-40 to 125	(MAP, MAS, MAU)
LM2903DGKR.A	Active	Production	VSSOP (DGK) | 8	2500 | LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	(MAP, MAS, MAU)
LM2903DR	Active	Production	SOIC (D) | 8	2500 | LARGE T&R	Yes	NIPDAU | SN	Level-1-260C-UNLIM	-40 to 125	LM2903
LM2903DR.A	Active	Production	SOIC (D) | 8	2500 | LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	LM2903
LM2903DRG3	Active	Production	SOIC (D) | 8	2500 | LARGE T&R	Yes	SN	Level-1-260C-UNLIM	-40 to 125	LM2903
LM2903DRG3.A	Active	Production	SOIC (D) | 8	2500 | LARGE T&R	Yes	SN	Level-1-260C-UNLIM	-40 to 125	LM2903
LM2903P	Active	Production	PDIP (P) | 8	50 | TUBE	Yes	NIPDAU	N/A for Pkg Type	-40 to 125	LM2903P
LM2903P.A	Active	Production	PDIP (P) | 8	50 | TUBE	Yes	NIPDAU	N/A for Pkg Type	-40 to 125	LM2903P
LM2903P.B	Active	Production	PDIP (P) | 8	50 | TUBE	Yes	NIPDAU	N/A for Pkg Type	-40 to 125	LM2903P
LM2903PSR	Active	Production	SO (PS) | 8	2000 | LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	L2903
LM2903PSR.A	Active	Production	SO (PS) | 8	2000 | LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	L2903
LM2903PWR	Active	Production	TSSOP (PW) | 8	2000 | LARGE T&R	Yes	NIPDAU | SN	Level-1-260C-UNLIM	-40 to 125	L2903
LM2903PWR.A	Active	Production	TSSOP (PW) | 8	2000 | LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	L2903
LM2903PWR.B	Active	Production	TSSOP (PW) | 8	2000 | LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	L2903
LM2903PWRG3	Active	Production	TSSOP (PW) | 8	2000 | LARGE T&R	Yes	SN	Level-1-260C-UNLIM	-40 to 125	L2903
LM2903PWRG3.A	Active	Production	TSSOP (PW) | 8	2000 | LARGE T&R	Yes	SN	Level-1-260C-UNLIM	-40 to 125	L2903
LM2903PWRG4	Active	Production	TSSOP (PW) | 8	2000 | LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	L2903
LM2903PWRG4.A	Active	Production	TSSOP (PW) | 8	2000 | LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	L2903
LM2903PWRG4.B	Active	Production	TSSOP (PW) | 8	2000 | LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	L2903
LM2903QD	Active	Production	SOIC (D) | 8	75 | TUBE	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	2903Q
LM2903QD.A	Active	Production	SOIC (D) | 8	75 | TUBE	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	2903Q

Orderable part number	Status (1)	Material type (2)	Package | Pins	Package qty | Carrier	RoHS (3)	Lead finish/ Ball material (4)	MSL rating/ Peak reflow (5)	Op temp (°C)	Part marking (6)
LM2903QDRG4	Obsolete	Production	SOIC (D) | 8	-	-	Call TI	Call TI	-40 to 125	2903Q
LM2903VQDR	Active	Production	SOIC (D) | 8	2500 | LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	L2903V
LM2903VQDR.A	Active	Production	SOIC (D) | 8	2500 | LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	L2903V
LM2903VQDRG4	Obsolete	Production	SOIC (D) | 8	-	-	Call TI	Call TI	-40 to 125	L2903V
LM2903VQPWR	Active	Production	TSSOP (PW) | 8	2000 | LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	L2903V
LM2903VQPWR.A	Active	Production	TSSOP (PW) | 8	2000 | LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	L2903V
LM2903VQPWR.B	Active	Production	TSSOP (PW) | 8	2000 | LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	L2903V
LM2903VQPWRG4	Obsolete	Production	TSSOP (PW) | 8	-	-	Call TI	Call TI	-40 to 125	L2903V
LM293ADGKR	Active	Production	VSSOP (DGK) | 8	2500 | LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-25 to 85	(MDP, MDS, MDU)
LM293ADGKR.A	Active	Production	VSSOP (DGK) | 8	2500 | LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-25 to 85	(MDP, MDS, MDU)
LM293ADGKRG4	Active	Production	VSSOP (DGK) | 8	2500 | LARGE T&R	-	Call TI	Call TI	-25 to 85	
LM293ADR	Active	Production	SOIC (D) | 8	2500 | LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-25 to 85	LM293A
LM293ADR.A	Active	Production	SOIC (D) | 8	2500 | LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-25 to 85	LM293A
LM293D	Obsolete	Production	SOIC (D) | 8	-	-	Call TI	Call TI	-25 to 85	LM293
LM293DGKR	Active	Production	VSSOP (DGK) | 8	2500 | LARGE T&R	Yes	NIPDAU | SN	Level-1-260C-UNLIM	-25 to 85	(MCP, MCS, MCU)
LM293DGKR.A	Active	Production	VSSOP (DGK) | 8	2500 | LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-25 to 85	(MCP, MCS, MCU)
LM293DGKR.B	Active	Production	VSSOP (DGK) | 8	2500 | LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-25 to 85	(MCP, MCS, MCU)
LM293DGKRG4	Active	Production	VSSOP (DGK) | 8	2500 | LARGE T&R	-	Call TI	Call TI	-25 to 85	
LM293DR	Active	Production	SOIC (D) | 8	2500 | LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-25 to 85	LM293
LM293DR.A	Active	Production	SOIC (D) | 8	2500 | LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-25 to 85	LM293
LM293DRG3	Active	Production	SOIC (D) | 8	2500 | LARGE T&R	Yes	SN	Level-1-260C-UNLIM	-25 to 85	LM293
LM293DRG3.A	Active	Production	SOIC (D) | 8	2500 | LARGE T&R	Yes	SN	Level-1-260C-UNLIM	-25 to 85	LM293
LM293P	Active	Production	PDIP (P) | 8	50 | TUBE	Yes	NIPDAU	N/A for Pkg Type	-25 to 85	LM293P
LM293P.A	Active	Production	PDIP (P) | 8	50 | TUBE	Yes	NIPDAU	N/A for Pkg Type	-25 to 85	LM293P
LM293P.B	Active	Production	PDIP (P) | 8	50 | TUBE	Yes	NIPDAU	N/A for Pkg Type	-25 to 85	LM293P
LM293PE4	Active	Production	PDIP (P) | 8	50 | TUBE	-	Call TI	Call TI	-25 to 85	
LM393ADGKR	Active	Production	VSSOP (DGK) | 8	2500 | LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	0 to 70	(M8P, M8S, M8U)
LM393ADGKR.A	Active	Production	VSSOP (DGK) | 8	2500 | LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	0 to 70	(M8P, M8S, M8U)
LM393ADGKRG4	Active	Production	VSSOP (DGK) | 8	2500 | LARGE T&R	-	Call TI	Call TI	0 to 70	
LM393ADR	Active	Production	SOIC (D) | 8	2500 | LARGE T&R	Yes	NIPDAU | SN	Level-1-260C-UNLIM	0 to 70	LM393A
LM393ADR.A	Active	Production	SOIC (D) | 8	2500 | LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	0 to 70	LM393A

Orderable part number	Status (1)	Material type (2)	Package | Pins	Package qty | Carrier	RoHS (3)	Lead finish/ Ball material (4)	MSL rating/ Peak reflow (5)	Op temp (°C)	Part marking (6)
LM393ADRG4	Obsolete	Production	SOIC (D) | 8	-	-	Call TI	Call TI	0 to 70	LM393A
LM393AP	Active	Production	PDIP (P) | 8	50 | TUBE	Yes	NIPDAU | SN	N/A for Pkg Type	0 to 70	LM393AP
LM393AP.A	Active	Production	PDIP (P) | 8	50 | TUBE	Yes	NIPDAU	N/A for Pkg Type	0 to 70	LM393AP
LM393AP.B	Active	Production	PDIP (P) | 8	50 | TUBE	Yes	NIPDAU	N/A for Pkg Type	0 to 70	LM393AP
LM393APE4	Active	Production	PDIP (P) | 8	50 | TUBE	-	Call TI	Call TI	0 to 70	
LM393APSR	Active	Production	SO (PS) | 8	2000 | LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	0 to 70	L393A
LM393APSR.A	Active	Production	SO (PS) | 8	2000 | LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	0 to 70	L393A
LM393APWR	Active	Production	TSSOP (PW) | 8	2000 | LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	0 to 70	L393A
LM393APWR.A	Active	Production	TSSOP (PW) | 8	2000 | LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	0 to 70	L393A
LM393APWR.B	Active	Production	TSSOP (PW) | 8	2000 | LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	0 to 70	L393A
LM393APWRG4	Obsolete	Production	TSSOP (PW) | 8	-	-	Call TI	Call TI	0 to 70	L393A
LM393BIDDFR	Active	Production	SOT-23-THIN (DDF) | 8	3000 | LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 85	393B
LM393BIDDFR.B	Active	Production	SOT-23-THIN (DDF) | 8	3000 | LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 85	393B
LM393BIDDFRG4	Active	Production	SOT-23-THIN (DDF) | 8	3000 | LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 85	393B
LM393BIDDFRG4.B	Active	Production	SOT-23-THIN (DDF) | 8	3000 | LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 85	393B
LM393BIDGKR	Active	Production	VSSOP (DGK) | 8	2500 | LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 85	393B
LM393BIDGKR.A	Active	Production	VSSOP (DGK) | 8	2500 | LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 85	393B
LM393BIDGKR.B	Active	Production	VSSOP (DGK) | 8	2500 | LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 85	393B
LM393BIDR	Active	Production	SOIC (D) | 8	2500 | LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 85	LM393B
LM393BIDR.A	Active	Production	SOIC (D) | 8	2500 | LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 85	LM393B
LM393BIDR.B	Active	Production	SOIC (D) | 8	2500 | LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 85	LM393B
LM393BIDRG4	Active	Production	SOIC (D) | 8	2500 | LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 85	LM393B
LM393BIDRG4.A	Active	Production	SOIC (D) | 8	2500 | LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 85	LM393B
LM393BIDRG4.B	Active	Production	SOIC (D) | 8	2500 | LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 85	LM393B
LM393BIDSGR	Active	Production	WSON (DSG) | 8	3000 | LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 85	393B
LM393BIDSGR.A	Active	Production	WSON (DSG) | 8	3000 | LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 85	393B
LM393BIDSGR.B	Active	Production	WSON (DSG) | 8	3000 | LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 85	393B
LM393BIDSGRG4	Active	Production	WSON (DSG) | 8	3000 | LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 85	393B
LM393BIDSGRG4.A	Active	Production	WSON (DSG) | 8	3000 | LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 85	393B
LM393BIDSGRG4.B	Active	Production	WSON (DSG) | 8	3000 | LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 85	393B
LM393BIPWR	Active	Production	TSSOP (PW) | 8	2000 | LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 85	LM393B

Orderable part number	Status (1)	Material type (2)	Package | Pins	Package qty | Carrier	RoHS (3)	Lead finish/ Ball material (4)	MSL rating/ Peak reflow (5)	Op temp (°C)	Part marking (6)
LM393BIPWR.A	Active	Production	TSSOP (PW) | 8	2000 | LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 85	LM393B
LM393BIPWR.B	Active	Production	TSSOP (PW) | 8	2000 | LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 85	LM393B
LM393DGKR	Active	Production	VSSOP (DGK) | 8	2500 | LARGE T&R	Yes	NIPDAU | SN	Level-1-260C-UNLIM	0 to 70	(M9P, M9S, M9U)
LM393DGKR.A	Active	Production	VSSOP (DGK) | 8	2500 | LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	0 to 70	(M9P, M9S, M9U)
LM393DGKRG4	Active	Production	VSSOP (DGK) | 8	2500 | LARGE T&R	-	Call TI	Call TI	0 to 70	
LM393DR	Active	Production	SOIC (D) | 8	2500 | LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	0 to 70	LM393
LM393DR.A	Active	Production	SOIC (D) | 8	2500 | LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	0 to 70	LM393
LM393DRG3	Active	Production	SOIC (D) | 8	2500 | LARGE T&R	Yes	SN	Level-1-260C-UNLIM	0 to 70	LM393
LM393DRG3.A	Active	Production	SOIC (D) | 8	2500 | LARGE T&R	Yes	SN	Level-1-260C-UNLIM	0 to 70	LM393
LM393DRG4	Obsolete	Production	SOIC (D) | 8	-	-	Call TI	Call TI	0 to 70	LM393
LM393P	Active	Production	PDIP (P) | 8	50 | TUBE	Yes	NIPDAU | SN	N/A for Pkg Type	0 to 70	LM393P
LM393P.A	Active	Production	PDIP (P) | 8	50 | TUBE	Yes	NIPDAU	N/A for Pkg Type	0 to 70	LM393P
LM393P.B	Active	Production	PDIP (P) | 8	50 | TUBE	Yes	NIPDAU	N/A for Pkg Type	0 to 70	LM393P
LM393PE3	Active	Production	PDIP (P) | 8	50 | TUBE	Yes	SN	N/A for Pkg Type	0 to 70	LM393P
LM393PE3.A	Active	Production	PDIP (P) | 8	50 | TUBE	Yes	SN	N/A for Pkg Type	0 to 70	LM393P
LM393PE4	Active	Production	PDIP (P) | 8	50 | TUBE	Yes	NIPDAU	N/A for Pkg Type	0 to 70	LM393P
LM393PE4.A	Active	Production	PDIP (P) | 8	50 | TUBE	Yes	NIPDAU	N/A for Pkg Type	0 to 70	LM393P
LM393PE4.B	Active	Production	PDIP (P) | 8	50 | TUBE	Yes	NIPDAU	N/A for Pkg Type	0 to 70	LM393P
LM393PS	Active	Production	SO (PS) | 8	80 | TUBE	Yes	NIPDAU	Level-1-260C-UNLIM	0 to 70	L393
LM393PS.A	Active	Production	SO (PS) | 8	80 | TUBE	Yes	NIPDAU	Level-1-260C-UNLIM	0 to 70	L393
LM393PSR	Active	Production	SO (PS) | 8	2000 | LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	0 to 70	L393
LM393PSR.A	Active	Production	SO (PS) | 8	2000 | LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	0 to 70	L393
LM393PSRG4	Active	Production	SO (PS) | 8	2000 | LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	0 to 70	L393
LM393PWR	Active	Production	TSSOP (PW) | 8	2000 | LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	0 to 70	L393
LM393PWR.A	Active	Production	TSSOP (PW) | 8	2000 | LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	0 to 70	L393
LM393PWR.B	Active	Production	TSSOP (PW) | 8	2000 | LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	0 to 70	L393
LM393PWRG3	Active	Production	TSSOP (PW) | 8	2000 | LARGE T&R	Yes	SN	Level-1-260C-UNLIM	0 to 70	L393
LM393PWRG3.A	Active	Production	TSSOP (PW) | 8	2000 | LARGE T&R	Yes	SN	Level-1-260C-UNLIM	0 to 70	L393
LM393PWRG4	Active	Production	TSSOP (PW) | 8	2000 | LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	0 to 70	L393
LM393PWRG4.A	Active	Production	TSSOP (PW) | 8	2000 | LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	0 to 70	L393
LM393PWRG4.B	Active	Production	TSSOP (PW) | 8	2000 | LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	0 to 70	L393

(1) **Status:** For more details on status, see our product life cycle.

(2) **Material type:** When designated, preproduction parts are prototypes/experimental devices, and are not yet approved or released for full production. Testing and final process, including without limitation quality assurance, reliability performance testing, and/or process qualification, may not yet be complete, and this item is subject to further changes or possible discontinuation. If available for ordering, purchases will be subject to an additional waiver at checkout, and are intended for early internal evaluation purposes only. These items are sold without warranties of any kind.

(3) **RoHS values:** Yes, No, RoHS Exempt. See the TI RoHS Statement for additional information and value definition.

(4) **Lead finish/Ball material:** Parts may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.

(5) **MSL rating/Peak reflow:** The moisture sensitivity level ratings and peak solder (reflow) temperatures. In the event that a part has multiple moisture sensitivity ratings, only the lowest level per JEDEC standards is shown. Refer to the shipping label for the actual reflow temperature that will be used to mount the part to the printed circuit board.

(6) **Part marking:** There may be an additional marking, which relates to the logo, the lot trace code information, or the environmental category of the part.

Multiple part markings will be inside parentheses. Only one part marking contained in parentheses and separated by a "~" will appear on a part. If a line is indented then it is a continuation of the previous line and the two combined represent the entire part marking for that device.

Important Information and Disclaimer: The information provided on this page represents TI's knowledge and belief as of the date that it is provided. TI bases its knowledge and belief on information provided by third parties, and makes no representation or warranty as to the accuracy of such information. Efforts are underway to better integrate information from third parties. TI has taken and continues to take reasonable steps to provide representative and accurate information but may not have conducted destructive testing or chemical analysis on incoming materials and chemicals. TI and TI suppliers consider certain information to be proprietary, and thus CAS numbers and other limited information may not be available for release.

In no event shall TI's liability arising out of such information exceed the total purchase price of the TI part(s) at issue in this document sold by TI to Customer on an annual basis.

OTHER QUALIFIED VERSIONS OF LM2903, LM2903B, LM293 :

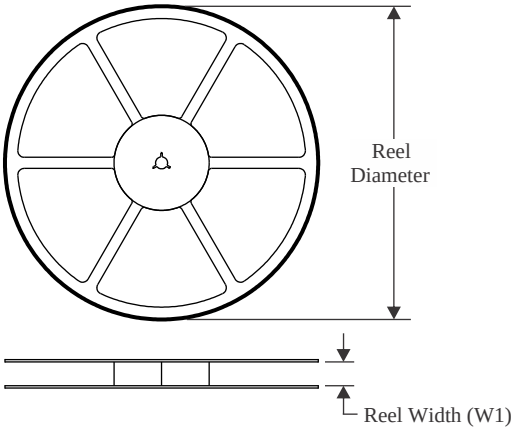
- Automotive : LM2903-Q1, LM2903B-Q1
- Enhanced Product : LM293-EP

NOTE: Qualified Version Definitions:

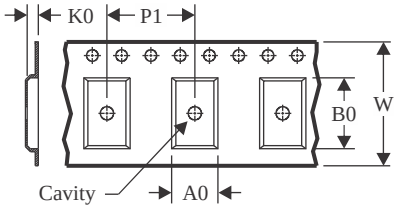
- Automotive - Q100 devices qualified for high-reliability automotive applications targeting zero defects
- Enhanced Product - Supports Defense, Aerospace and Medical Applications

TAPE AND REEL INFORMATION

REEL DIMENSIONS

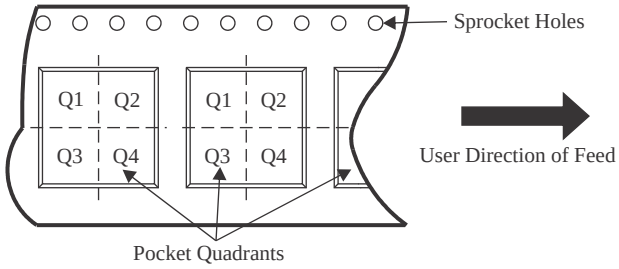


TAPE DIMENSIONS



A0	Dimension designed to accommodate the component width
B0	Dimension designed to accommodate the component length
K0	Dimension designed to accommodate the component thickness
W	Overall width of the carrier tape
P1	Pitch between successive cavity centers

QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE



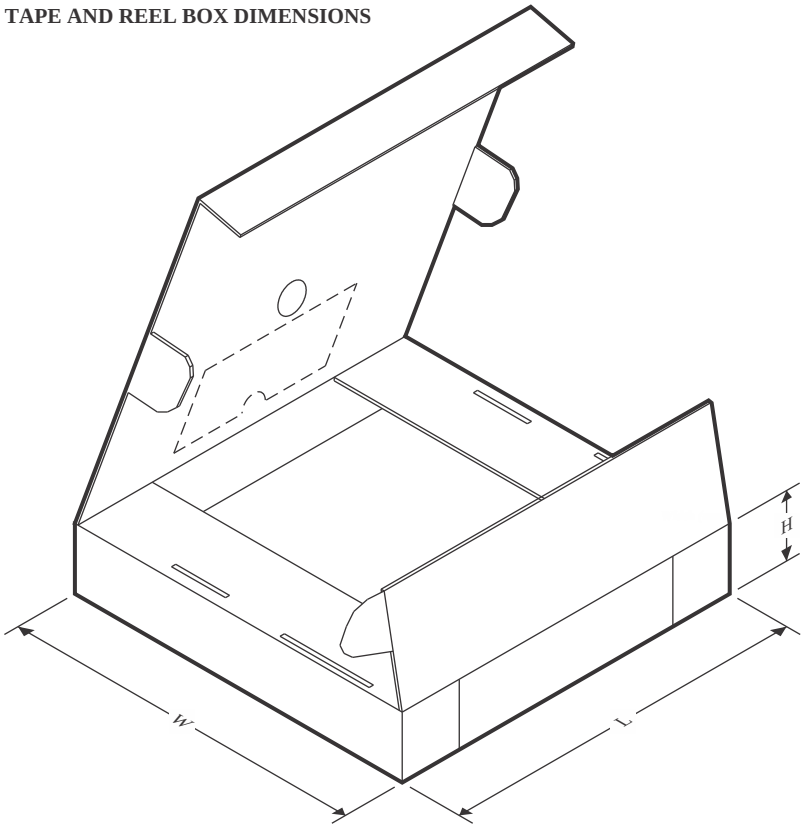
*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
LM193DR	SOIC	D	8	2500	330.0	12.4	6.4	5.2	2.1	8.0	12.0	Q1
LM193DRG4	SOIC	D	8	2500	330.0	12.4	6.4	5.2	2.1	8.0	12.0	Q1
LM2903AVQDR	SOIC	D	8	2500	330.0	12.4	6.4	5.2	2.1	8.0	12.0	Q1
LM2903AVQDR	SOIC	D	8	2500	330.0	12.5	6.4	5.2	2.1	8.0	12.0	Q1
LM2903AVQDR	SOIC	D	8	2500	330.0	12.4	6.4	5.2	2.1	8.0	12.0	Q1
LM2903AVQDRG4	SOIC	D	8	2500	330.0	12.4	6.4	5.2	2.1	8.0	12.0	Q1
LM2903AVQPWR	TSSOP	PW	8	2000	330.0	12.4	7.0	3.6	1.6	8.0	12.0	Q1
LM2903AVQPWRG4	TSSOP	PW	8	2000	330.0	12.4	7.0	3.6	1.6	8.0	12.0	Q1
LM2903BIDDFR	SOT-23-THIN	DDF	8	3000	180.0	8.4	3.2	3.2	1.4	4.0	8.0	Q3
LM2903BIDDFRG4	SOT-23-THIN	DDF	8	3000	180.0	8.4	3.2	3.2	1.4	4.0	8.0	Q3
LM2903BIDGKR	VSSOP	DGK	8	2500	330.0	12.4	6.4	5.2	2.1	8.0	12.0	Q1
LM2903BIDGKR	VSSOP	DGK	8	2500	330.0	12.4	5.3	3.4	1.4	8.0	12.0	Q1
LM2903BIDGKRG4	VSSOP	DGK	8	2500	330.0	12.4	5.3	3.4	1.4	8.0	12.0	Q1
LM2903BIDR	SOIC	D	8	2500	330.0	12.4	6.4	5.2	2.1	8.0	12.0	Q1
LM2903BIDRG4	SOIC	D	8	2500	330.0	12.4	6.4	5.2	2.1	8.0	12.0	Q1

Device	Package Type	Package Drawing	Pins	SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
LM2903BIDSGR	WSON	DSG	8	3000	180.0	8.4	2.3	2.3	1.15	4.0	8.0	Q2
LM2903BIDSGRG4	WSON	DSG	8	3000	180.0	8.4	2.3	2.3	1.15	4.0	8.0	Q2
LM2903BIPWR	TSSOP	PW	8	2000	330.0	12.4	7.0	3.6	1.6	8.0	12.0	Q1
LM2903DGKR	VSSOP	DGK	8	2500	330.0	12.4	6.4	5.2	2.1	8.0	12.0	Q1
LM2903DR	SOIC	D	8	2500	330.0	12.4	6.4	5.2	2.1	8.0	12.0	Q1
LM2903DR	SOIC	D	8	2500	330.0	12.4	6.4	5.2	2.1	8.0	12.0	Q1
LM2903DR	SOIC	D	8	2500	330.0	12.4	6.4	5.2	2.1	8.0	12.0	Q1
LM2903DRG3	SOIC	D	8	2500	330.0	12.8	6.4	5.2	2.1	8.0	12.0	Q1
LM2903PSR	SO	PS	8	2000	330.0	16.4	8.35	6.6	2.4	12.0	16.0	Q1
LM2903PWR	TSSOP	PW	8	2000	330.0	12.4	7.0	3.6	1.6	8.0	12.0	Q1
LM2903PWRG3	TSSOP	PW	8	2000	330.0	12.4	7.0	3.6	1.6	8.0	12.0	Q1
LM2903PWRG4	TSSOP	PW	8	2000	330.0	12.4	7.0	3.6	1.6	8.0	12.0	Q1
LM2903VQDR	SOIC	D	8	2500	330.0	12.4	6.4	5.2	2.1	8.0	12.0	Q1
LM2903VQPWR	TSSOP	PW	8	2000	330.0	12.4	7.0	3.6	1.6	8.0	12.0	Q1
LM293ADGKR	VSSOP	DGK	8	2500	330.0	12.4	5.3	3.4	1.4	8.0	12.0	Q1
LM293ADR	SOIC	D	8	2500	330.0	12.4	6.4	5.2	2.1	8.0	12.0	Q1
LM293ADR	SOIC	D	8	2500	330.0	12.4	6.4	5.2	2.1	8.0	12.0	Q1
LM293ADR	SOIC	D	8	2500	330.0	12.4	6.4	5.2	2.1	8.0	12.0	Q1
LM293DGKR	VSSOP	DGK	8	2500	330.0	12.4	5.3	3.4	1.4	8.0	12.0	Q1
LM293DR	SOIC	D	8	2500	330.0	12.4	6.4	5.2	2.1	8.0	12.0	Q1
LM293DR	SOIC	D	8	2500	330.0	12.4	6.4	5.2	2.1	8.0	12.0	Q1
LM293DR	SOIC	D	8	2500	330.0	12.4	6.4	5.2	2.1	8.0	12.0	Q1
LM293DRG3	SOIC	D	8	2500	330.0	12.8	6.4	5.2	2.1	8.0	12.0	Q1
LM393ADGKR	VSSOP	DGK	8	2500	330.0	12.4	5.3	3.4	1.4	8.0	12.0	Q1
LM393ADR	SOIC	D	8	2500	330.0	12.4	6.4	5.2	2.1	8.0	12.0	Q1
LM393ADR	SOIC	D	8	2500	330.0	12.4	6.4	5.2	2.1	8.0	12.0	Q1
LM393ADR	SOIC	D	8	2500	330.0	12.4	6.4	5.2	2.1	8.0	12.0	Q1
LM393APSR	SO	PS	8	2000	330.0	16.4	8.35	6.6	2.4	12.0	16.0	Q1
LM393APWR	TSSOP	PW	8	2000	330.0	12.4	7.0	3.6	1.6	8.0	12.0	Q1
LM393BIDDFR	SOT-23-THIN	DDF	8	3000	180.0	8.4	3.2	3.2	1.4	4.0	8.0	Q3
LM393BIDDFRG4	SOT-23-THIN	DDF	8	3000	180.0	8.4	3.2	3.2	1.4	4.0	8.0	Q3
LM393BIDGKR	VSSOP	DGK	8	2500	330.0	12.4	6.4	5.2	2.1	8.0	12.0	Q1
LM393BIDR	SOIC	D	8	2500	330.0	12.4	6.4	5.2	2.1	8.0	12.0	Q1
LM393BIDRG4	SOIC	D	8	2500	330.0	12.4	6.4	5.2	2.1	8.0	12.0	Q1
LM393BIDSGR	WSON	DSG	8	3000	180.0	8.4	2.3	2.3	1.15	4.0	8.0	Q2
LM393BIDSGRG4	WSON	DSG	8	3000	180.0	8.4	2.3	2.3	1.15	4.0	8.0	Q2
LM393BIPWR	TSSOP	PW	8	2000	330.0	12.4	7.0	3.6	1.6	8.0	12.0	Q1
LM393DGKR	VSSOP	DGK	8	2500	330.0	12.4	5.3	3.4	1.4	8.0	12.0	Q1
LM393DGKR	VSSOP	DGK	8	2500	330.0	12.4	6.4	5.2	2.1	8.0	12.0	Q1
LM393DR	SOIC	D	8	2500	330.0	12.4	6.4	5.2	2.1	8.0	12.0	Q1

Device	Package Type	Package Drawing	Pins	SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
LM393DR	SOIC	D	8	2500	330.0	12.4	6.4	5.2	2.1	8.0	12.0	Q1
LM393DR	SOIC	D	8	2500	330.0	12.4	6.4	5.2	2.1	8.0	12.0	Q1
LM393DRG3	SOIC	D	8	2500	330.0	12.8	6.4	5.2	2.1	8.0	12.0	Q1
LM393PSR	SO	PS	8	2000	330.0	16.4	8.35	6.6	2.4	12.0	16.0	Q1
LM393PWR	TSSOP	PW	8	2000	330.0	12.4	7.0	3.6	1.6	8.0	12.0	Q1
LM393PWRG3	TSSOP	PW	8	2000	330.0	12.4	7.0	3.6	1.6	8.0	12.0	Q1
LM393PWRG4	TSSOP	PW	8	2000	330.0	12.4	7.0	3.6	1.6	8.0	12.0	Q1

TAPE AND REEL BOX DIMENSIONS



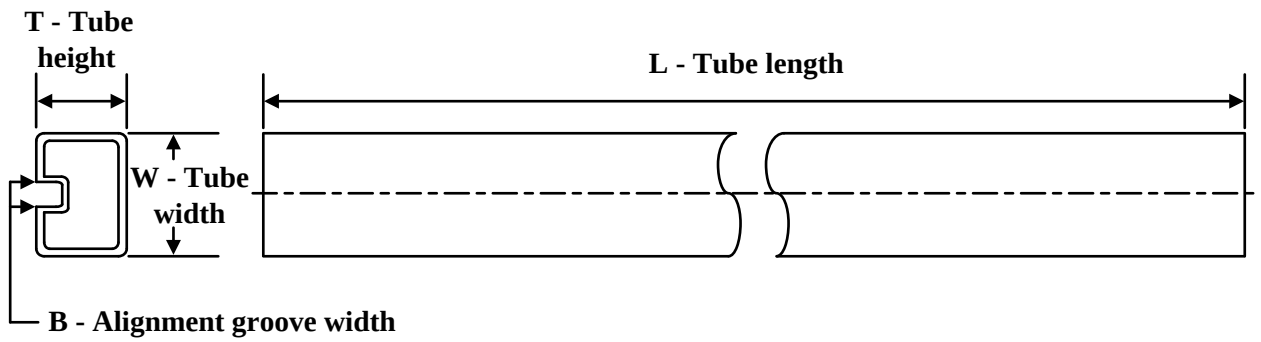
*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
LM193DR	SOIC	D	8	2500	353.0	353.0	32.0
LM193DRG4	SOIC	D	8	2500	353.0	353.0	32.0
LM2903AVQDR	SOIC	D	8	2500	340.5	338.1	20.6
LM2903AVQDR	SOIC	D	8	2500	353.0	353.0	32.0
LM2903AVQDR	SOIC	D	8	2500	353.0	353.0	32.0
LM2903AVQDRG4	SOIC	D	8	2500	353.0	353.0	32.0
LM2903AVQPWR	TSSOP	PW	8	2000	353.0	353.0	32.0
LM2903AVQPWRG4	TSSOP	PW	8	2000	353.0	353.0	32.0
LM2903BIDDFR	SOT-23-THIN	DDF	8	3000	210.0	185.0	35.0
LM2903BIDDFRG4	SOT-23-THIN	DDF	8	3000	210.0	185.0	35.0
LM2903BIDGKR	VSSOP	DGK	8	2500	353.0	353.0	32.0
LM2903BIDGKR	VSSOP	DGK	8	2500	353.0	353.0	32.0
LM2903BIDGKRG4	VSSOP	DGK	8	2500	353.0	353.0	32.0
LM2903BIDR	SOIC	D	8	2500	353.0	353.0	32.0
LM2903BIDRG4	SOIC	D	8	2500	353.0	353.0	32.0
LM2903BIDSGR	WSON	DSG	8	3000	210.0	185.0	35.0
LM2903BIDSGRG4	WSON	DSG	8	3000	210.0	185.0	35.0
LM2903BIPWR	TSSOP	PW	8	2000	353.0	353.0	32.0

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
LM2903DGKR	VSSOP	DGK	8	2500	353.0	353.0	32.0
LM2903DR	SOIC	D	8	2500	353.0	353.0	32.0
LM2903DR	SOIC	D	8	2500	353.0	353.0	32.0
LM2903DR	SOIC	D	8	2500	340.5	338.1	20.6
LM2903DRG3	SOIC	D	8	2500	364.0	364.0	27.0
LM2903PSR	SO	PS	8	2000	353.0	353.0	32.0
LM2903PWR	TSSOP	PW	8	2000	353.0	353.0	32.0
LM2903PWRG3	TSSOP	PW	8	2000	364.0	364.0	27.0
LM2903PWRG4	TSSOP	PW	8	2000	353.0	353.0	32.0
LM2903VQDR	SOIC	D	8	2500	353.0	353.0	32.0
LM2903VQPWR	TSSOP	PW	8	2000	353.0	353.0	32.0
LM293ADGKR	VSSOP	DGK	8	2500	353.0	353.0	32.0
LM293ADR	SOIC	D	8	2500	353.0	353.0	32.0
LM293ADR	SOIC	D	8	2500	340.5	338.1	20.6
LM293ADR	SOIC	D	8	2500	353.0	353.0	32.0
LM293DGKR	VSSOP	DGK	8	2500	356.0	356.0	35.0
LM293DR	SOIC	D	8	2500	353.0	353.0	32.0
LM293DR	SOIC	D	8	2500	353.0	353.0	32.0
LM293DR	SOIC	D	8	2500	340.5	338.1	20.6
LM293DRG3	SOIC	D	8	2500	364.0	364.0	27.0
LM393ADGKR	VSSOP	DGK	8	2500	353.0	353.0	32.0
LM393ADR	SOIC	D	8	2500	353.0	353.0	32.0
LM393ADR	SOIC	D	8	2500	353.0	353.0	32.0
LM393ADR	SOIC	D	8	2500	340.5	338.1	20.6
LM393APSR	SO	PS	8	2000	353.0	353.0	32.0
LM393APWR	TSSOP	PW	8	2000	353.0	353.0	32.0
LM393BIDDFR	SOT-23-THIN	DDF	8	3000	210.0	185.0	35.0
LM393BIDDFRG4	SOT-23-THIN	DDF	8	3000	210.0	185.0	35.0
LM393BIDGKR	VSSOP	DGK	8	2500	353.0	353.0	32.0
LM393BIDR	SOIC	D	8	2500	353.0	353.0	32.0
LM393BIDRG4	SOIC	D	8	2500	353.0	353.0	32.0
LM393BIDSGR	WSON	DSG	8	3000	210.0	185.0	35.0
LM393BIDSGRG4	WSON	DSG	8	3000	210.0	185.0	35.0
LM393BIPWR	TSSOP	PW	8	2000	353.0	353.0	32.0
LM393DGKR	VSSOP	DGK	8	2500	353.0	353.0	32.0
LM393DGKR	VSSOP	DGK	8	2500	353.0	353.0	32.0
LM393DR	SOIC	D	8	2500	340.5	338.1	20.6
LM393DR	SOIC	D	8	2500	353.0	353.0	32.0
LM393DR	SOIC	D	8	2500	353.0	353.0	32.0
LM393DRG3	SOIC	D	8	2500	364.0	364.0	27.0
LM393PSR	SO	PS	8	2000	353.0	353.0	32.0
LM393PWR	TSSOP	PW	8	2000	353.0	353.0	32.0
LM393PWRG3	TSSOP	PW	8	2000	364.0	364.0	27.0

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
LM393PWRG4	TSSOP	PW	8	2000	353.0	353.0	32.0

TUBE



*All dimensions are nominal

Device	Package Name	Package Type	Pins	SPQ	L (mm)	W (mm)	T (µm)	B (mm)
LM2903P	P	PDIP	8	50	506	13.97	11230	4.32
LM2903P	P	PDIP	8	50	506	13.97	11230	4.32
LM2903P.A	P	PDIP	8	50	506	13.97	11230	4.32
LM2903P.A	P	PDIP	8	50	506	13.97	11230	4.32
LM2903P.B	P	PDIP	8	50	506	13.97	11230	4.32
LM2903P.B	P	PDIP	8	50	506	13.97	11230	4.32
LM2903QD	D	SOIC	8	75	505.46	6.76	3810	4
LM2903QD.A	D	SOIC	8	75	505.46	6.76	3810	4
LM293P	P	PDIP	8	50	506	13.97	11230	4.32
LM293P.A	P	PDIP	8	50	506	13.97	11230	4.32
LM293P.B	P	PDIP	8	50	506	13.97	11230	4.32
LM393AP	P	PDIP	8	50	506.1	9	600	5.4
LM393AP	P	PDIP	8	50	506	13.97	11230	4.32
LM393AP.A	P	PDIP	8	50	506	13.97	11230	4.32
LM393AP.A	P	PDIP	8	50	506.1	9	600	5.4
LM393AP.B	P	PDIP	8	50	506	13.97	11230	4.32
LM393AP.B	P	PDIP	8	50	506.1	9	600	5.4
LM393P	P	PDIP	8	50	506	13.97	11230	4.32
LM393P	P	PDIP	8	50	506.1	9	600	5.4
LM393P.A	P	PDIP	8	50	506	13.97	11230	4.32
LM393P.A	P	PDIP	8	50	506.1	9	600	5.4
LM393P.B	P	PDIP	8	50	506	13.97	11230	4.32
LM393P.B	P	PDIP	8	50	506.1	9	600	5.4
LM393PE3	P	PDIP	8	50	506.1	9	600	5.4
LM393PE3.A	P	PDIP	8	50	506.1	9	600	5.4
LM393PE4	P	PDIP	8	50	506	13.97	11230	4.32
LM393PE4.A	P	PDIP	8	50	506	13.97	11230	4.32
LM393PE4.B	P	PDIP	8	50	506	13.97	11230	4.32
LM393PS	PS	SOP	8	80	530	10.5	4000	4.1

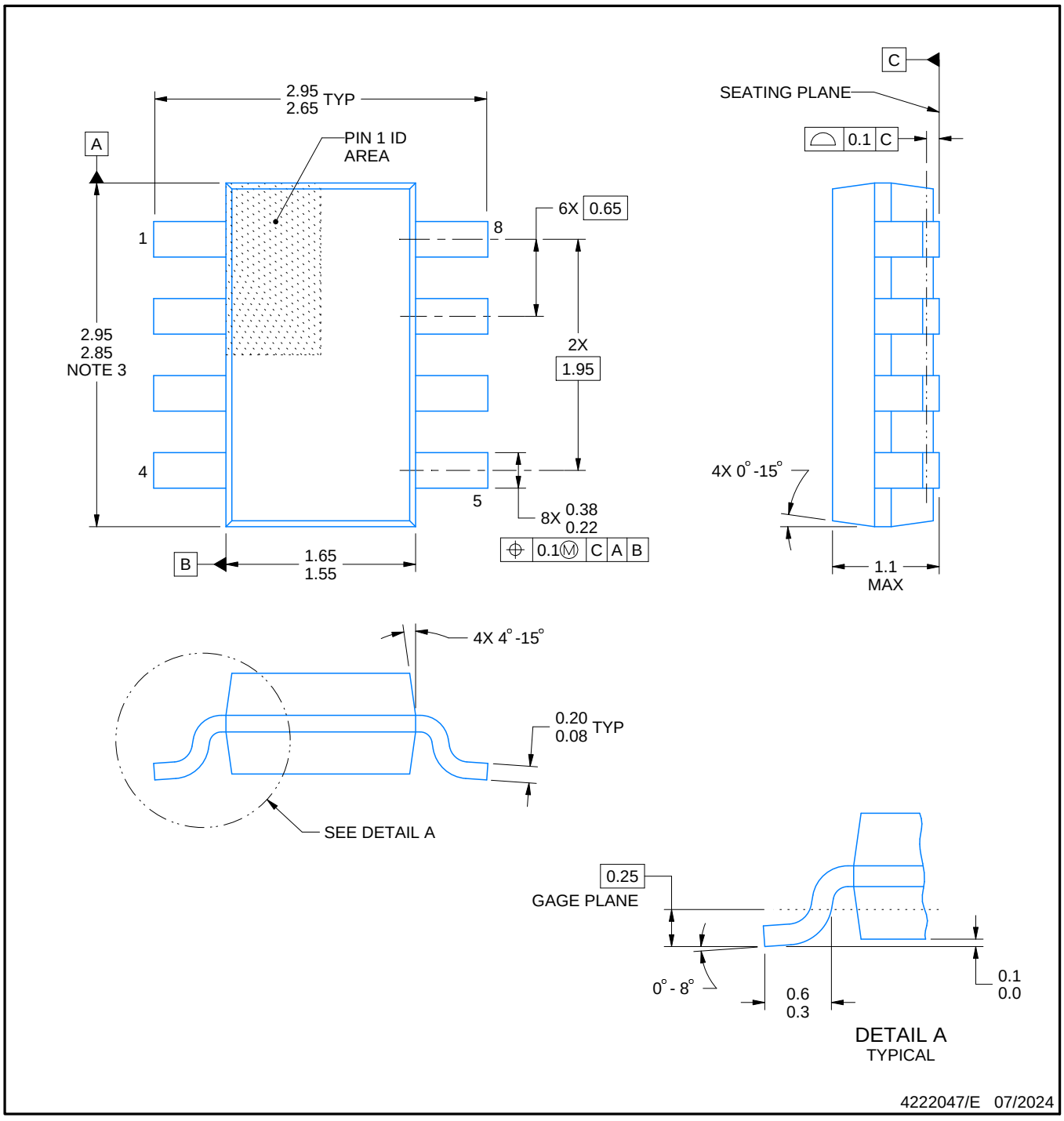
Device	Package Name	Package Type	Pins	SPQ	L (mm)	W (mm)	T (µm)	B (mm)
LM393PS.A	PS	SOP	8	80	530	10.5	4000	4.1

PACKAGE OUTLINE

DDF0008A

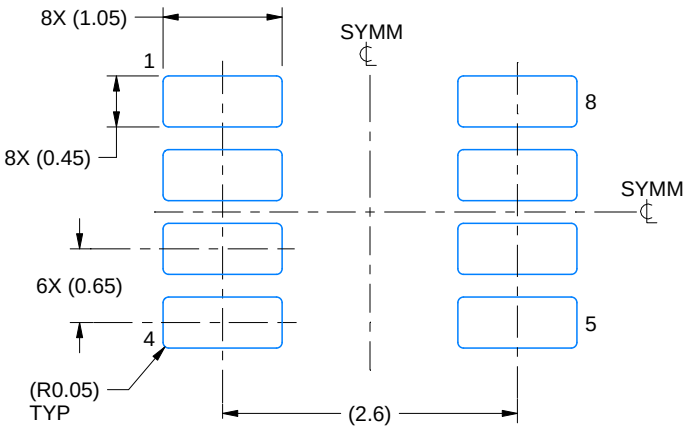
SOT-23-THIN - 1.1 mm max height

PLASTIC SMALL OUTLINE

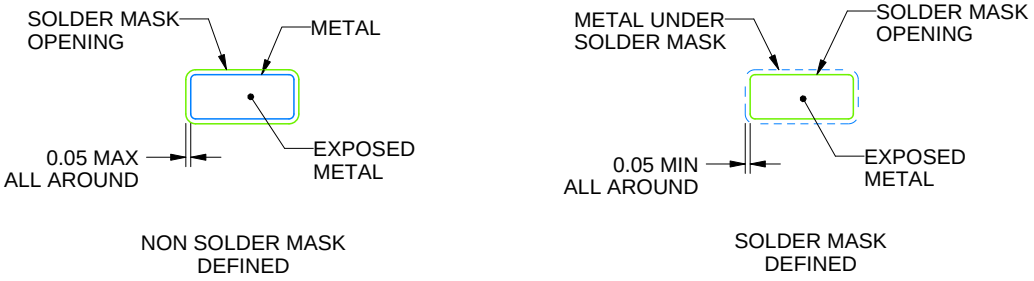


NOTES:

1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.
2. This drawing is subject to change without notice.
3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0.15 mm per side.



LAND PATTERN EXAMPLE
EXPOSED METAL SHOWN
SCALE:15X

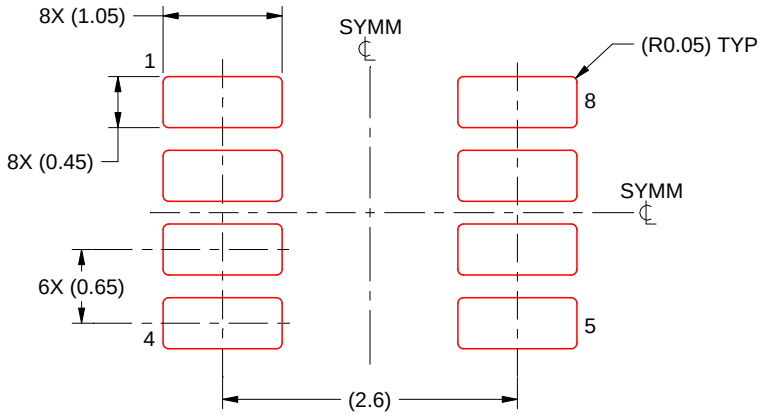


SOLDER MASK DETAILS

4222047/E 07/2024

NOTES: (continued)

4. Publication IPC-7351 may have alternate designs.
5. Solder mask tolerances between and around signal pads can vary based on board fabrication site.

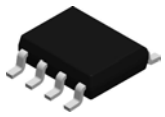


SOLDER PASTE EXAMPLE
BASED ON 0.125 mm THICK STENCIL
SCALE:15X

4222047/E 07/2024

NOTES: (continued)

6. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
7. Board assembly site may have different recommendations for stencil design.

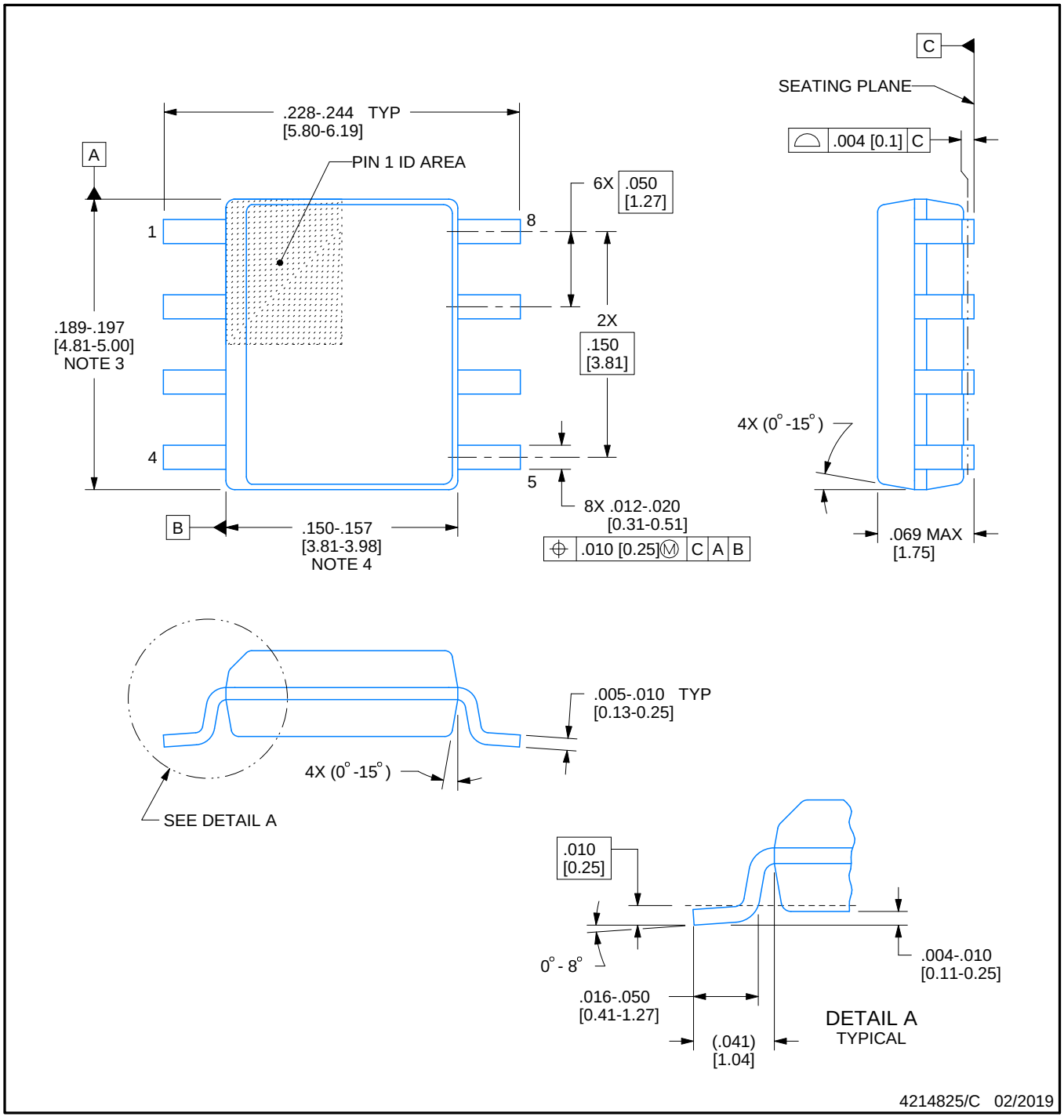


PACKAGE OUTLINE

D0008A

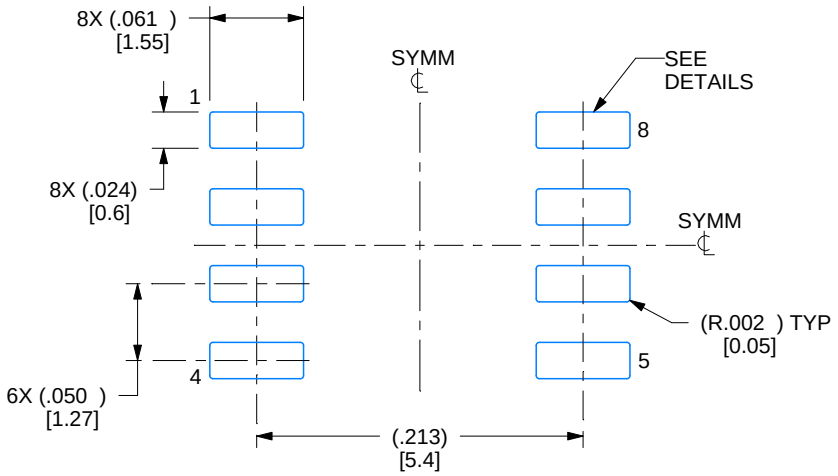
SOIC - 1.75 mm max height

SMALL OUTLINE INTEGRATED CIRCUIT

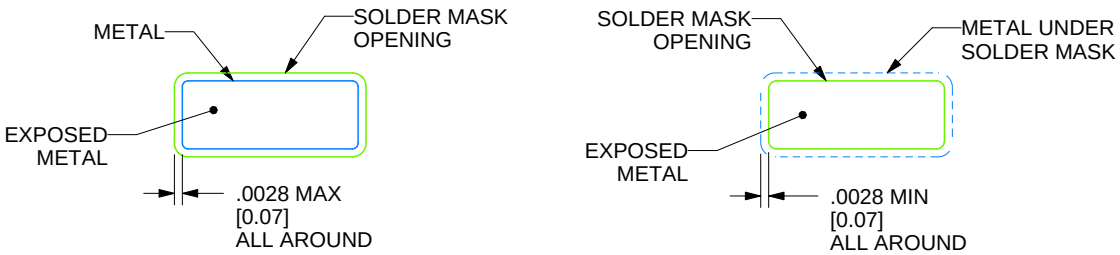


NOTES:

1. Linear dimensions are in inches [millimeters]. Dimensions in parenthesis are for reference only. Controlling dimensions are in inches. Dimensioning and tolerancing per ASME Y14.5M.
2. This drawing is subject to change without notice.
3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed .006 [0.15] per side.
4. This dimension does not include interlead flash.
5. Reference JEDEC registration MS-012, variation AA.



LAND PATTERN EXAMPLE
EXPOSED METAL SHOWN
SCALE:8X



SOLDER MASK DETAILS

4214825/C 02/2019

NOTES: (continued)

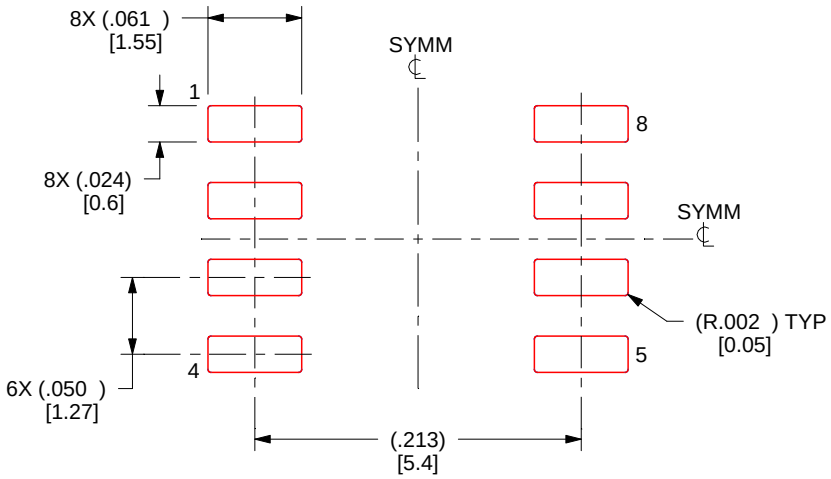
6. Publication IPC-7351 may have alternate designs.
7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.

EXAMPLE STENCIL DESIGN

D0008A

SOIC - 1.75 mm max height

SMALL OUTLINE INTEGRATED CIRCUIT



SOLDER PASTE EXAMPLE
BASED ON .005 INCH [0.125 MM] THICK STENCIL
SCALE:8X

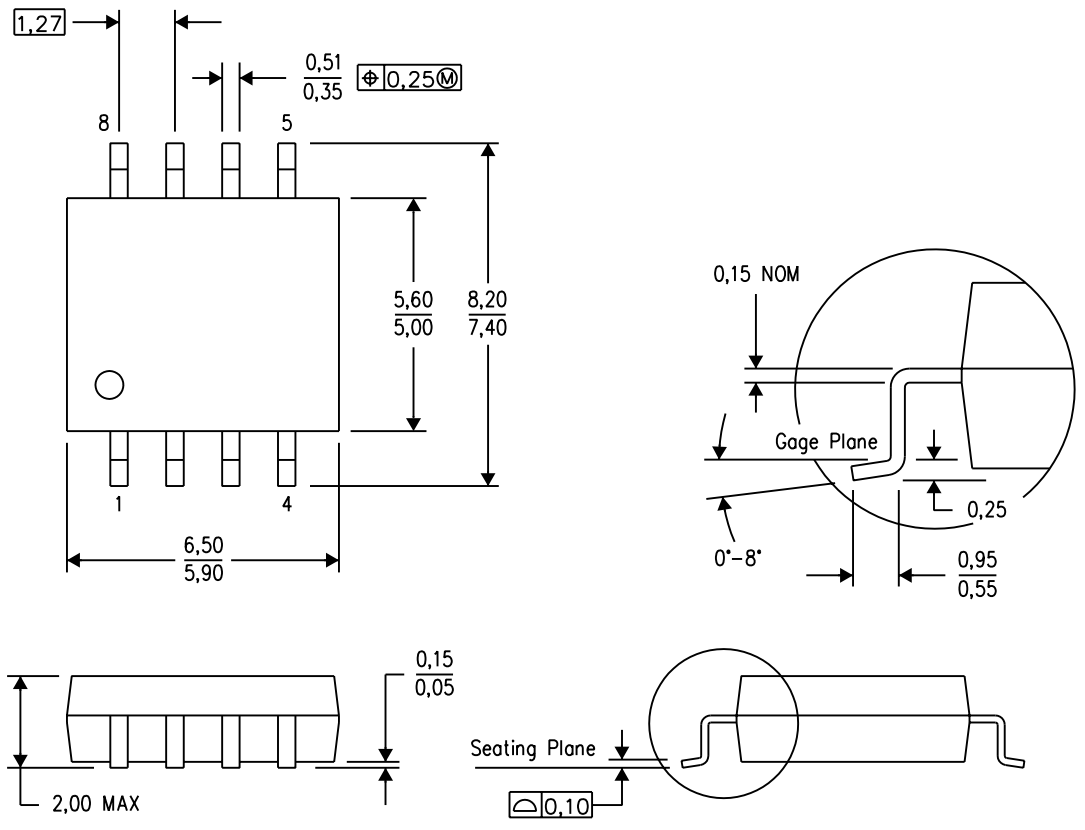
4214825/C 02/2019

NOTES: (continued)

8. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
9. Board assembly site may have different recommendations for stencil design.

MECHANICAL DATA

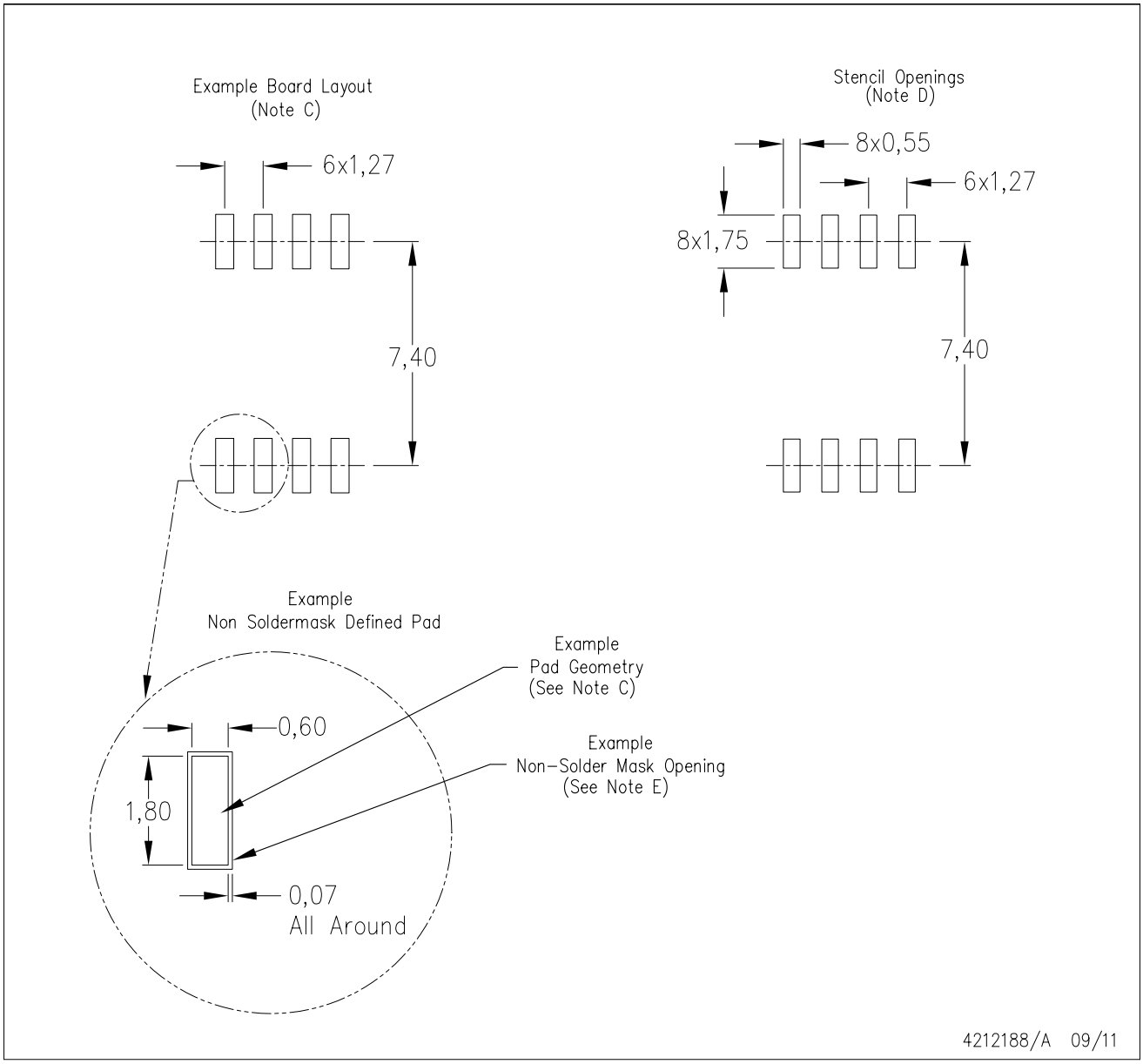
PS (R-PDSO-G8) **PLASTIC SMALL-OUTLINE PACKAGE**



4040063/C 03/03

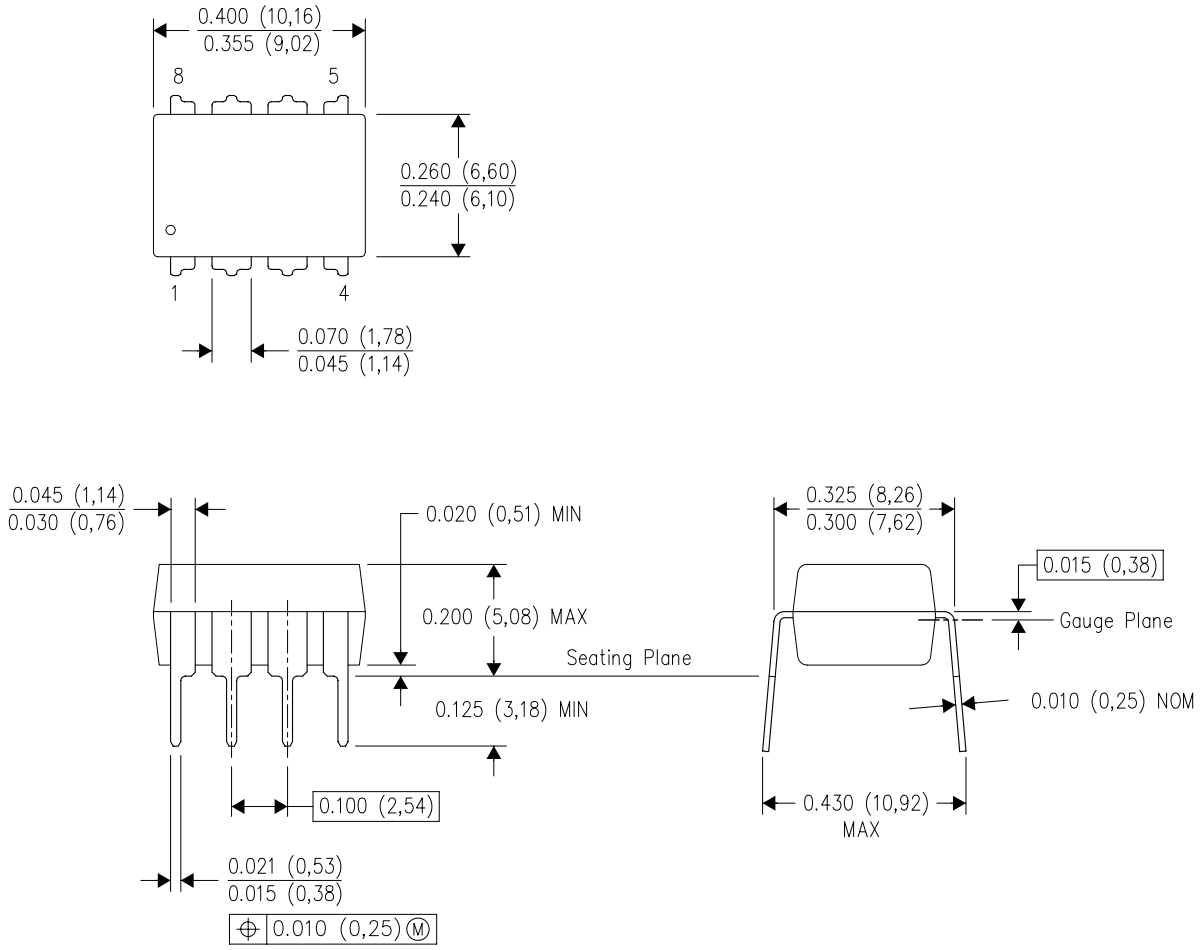
NOTES:
A. All linear dimensions are in millimeters.
B. This drawing is subject to change without notice.
C. Body dimensions do not include mold flash or protrusion, not to exceed 0,15.

PS (R–PDSO–G8) PLASTIC SMALL OUTLINE



NOTES:
A. All linear dimensions are in millimeters.
B. This drawing is subject to change without notice.
C. Publication IPC–7351 is recommended for alternate designs.
D. Laser cutting apertures with trapezoidal walls and also rounding corners will offer better paste release. Customers should contact their board assembly site for stencil design recommendations. Refer to IPC–7525 for other stencil recommendations.
E. Customers should contact their board fabrication site for solder mask tolerances between and around signal pads.

P (R–PDIP–T8) PLASTIC DUAL–IN–LINE PACKAGE



NOTES:
A. All linear dimensions are in inches (millimeters).
B. This drawing is subject to change without notice.
C. Falls within JEDEC MS–001 variation BA.

GENERIC PACKAGE VIEW

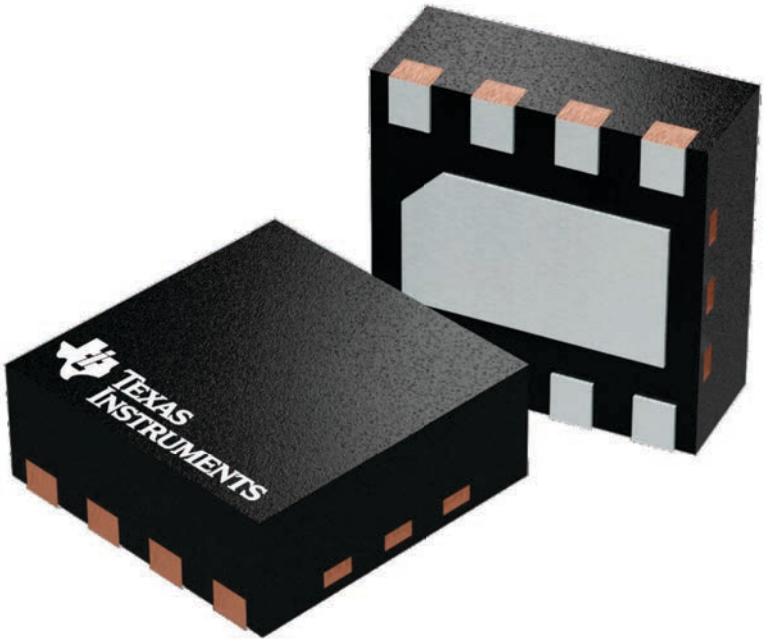
DSG 8

WSON - 0.8 mm max height

2 x 2, 0.5 mm pitch

PLASTIC SMALL OUTLINE - NO LEAD

This image is a representation of the package family, actual package may vary.
Refer to the product data sheet for package details.



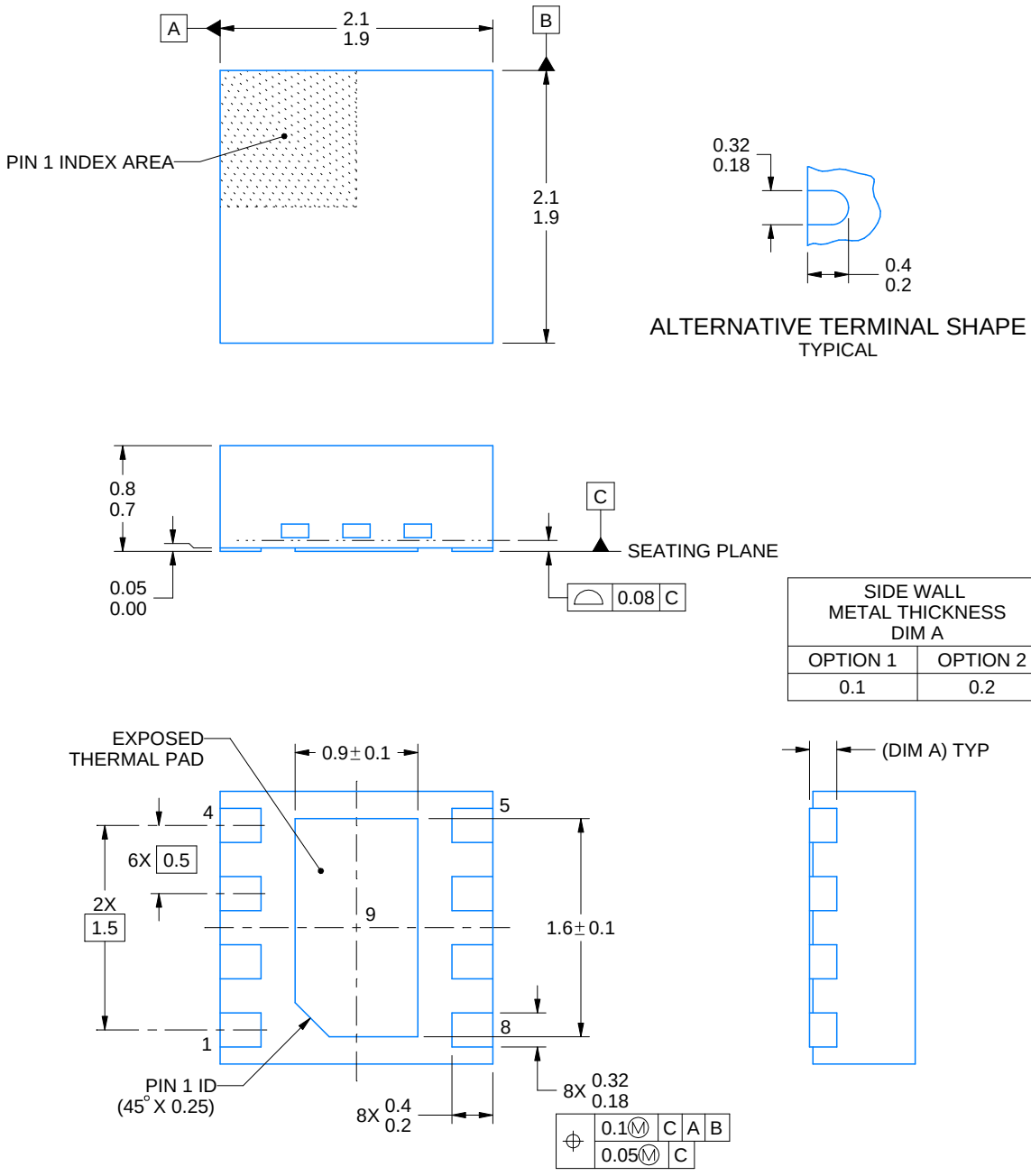
4224783/A

DSG0008A

PACKAGE OUTLINE

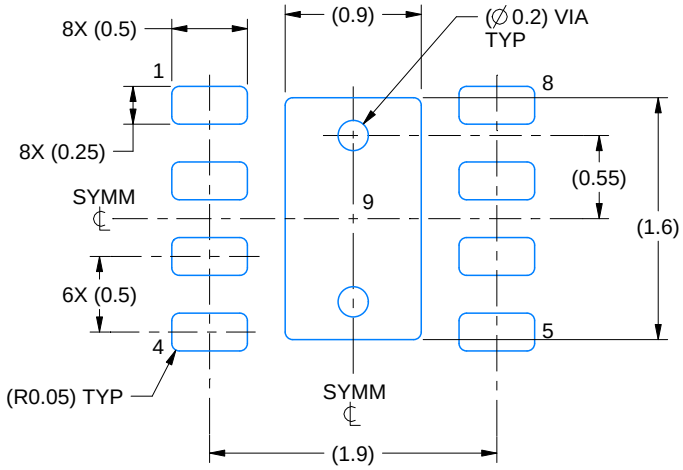
WSON - 0.8 mm max height

PLASTIC SMALL OUTLINE - NO LEAD

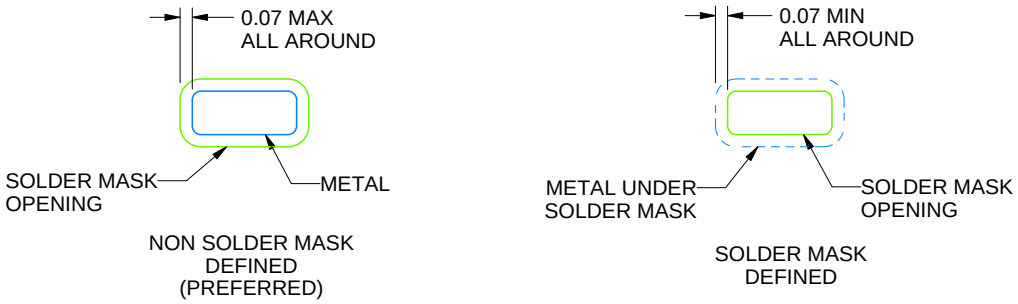


NOTES:

1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.
2. This drawing is subject to change without notice.
3. The package thermal pad must be soldered to the printed circuit board for thermal and mechanical performance.



LAND PATTERN EXAMPLE
SCALE:20X

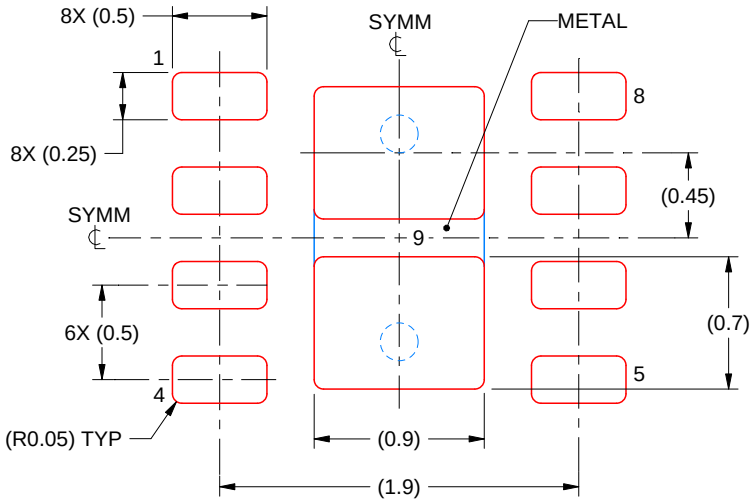


SOLDER MASK DETAILS

4218900/E 08/2022

NOTES: (continued)

4. This package is designed to be soldered to a thermal pad on the board. For more information, see Texas Instruments literature number SLUA271 (www.ti.com/lit/slua271).
5. Vias are optional depending on application, refer to device data sheet. If any vias are implemented, refer to their locations shown on this view. It is recommended that vias under paste be filled, plugged or tented.



SOLDER PASTE EXAMPLE
BASED ON 0.125 mm THICK STENCIL

EXPOSED PAD 9:
87% PRINTED SOLDER COVERAGE BY AREA UNDER PACKAGE
SCALE:25X

4218900/E 08/2022

NOTES: (continued)

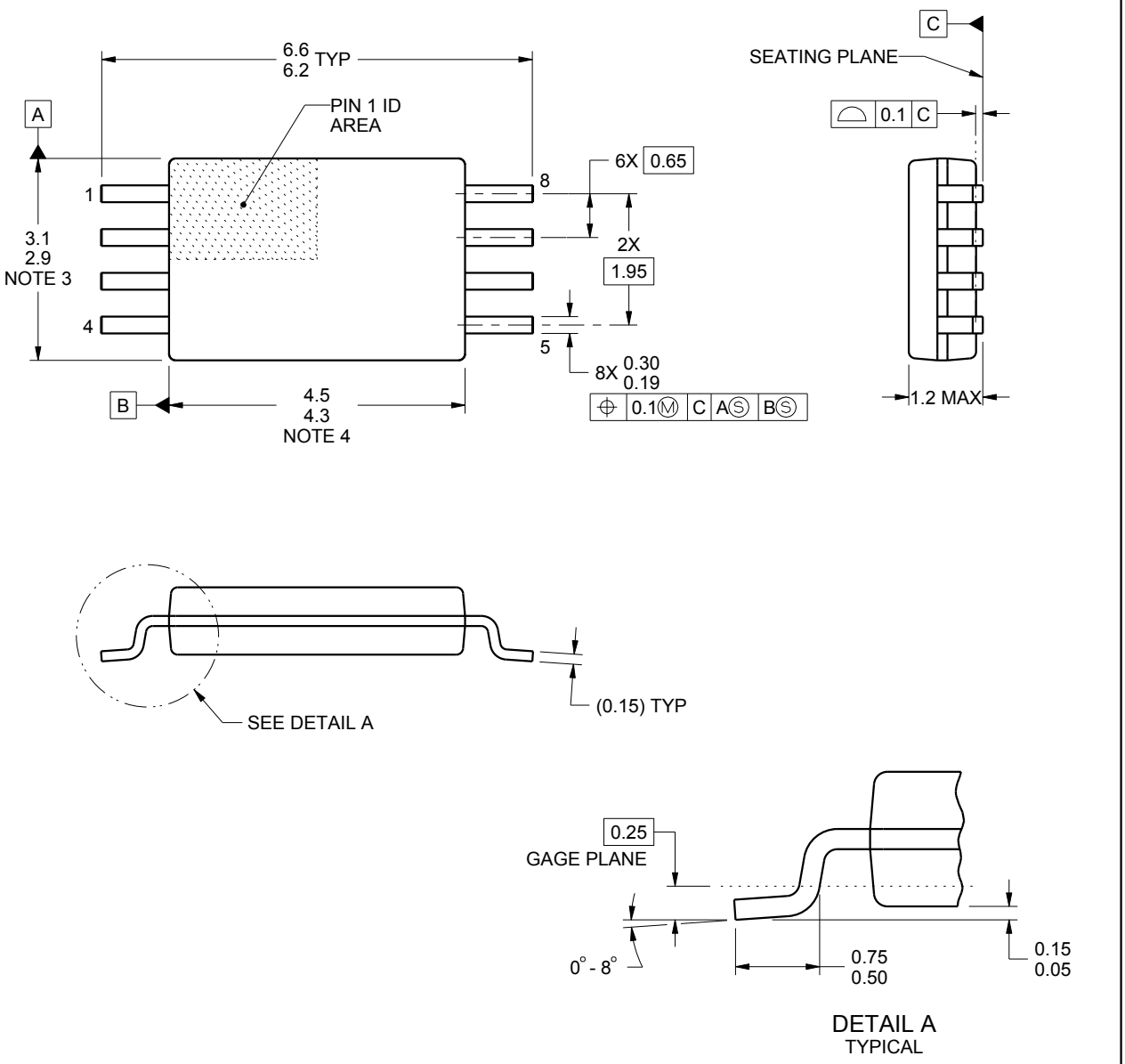
6. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.

PACKAGE OUTLINE

PW0008A

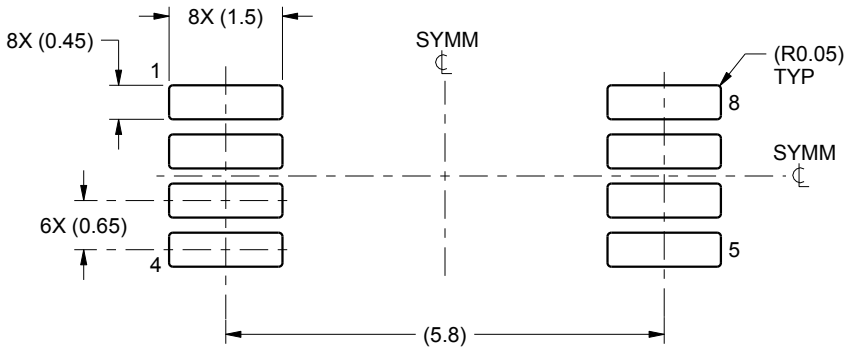
TSSOP - 1.2 mm max height

SMALL OUTLINE PACKAGE

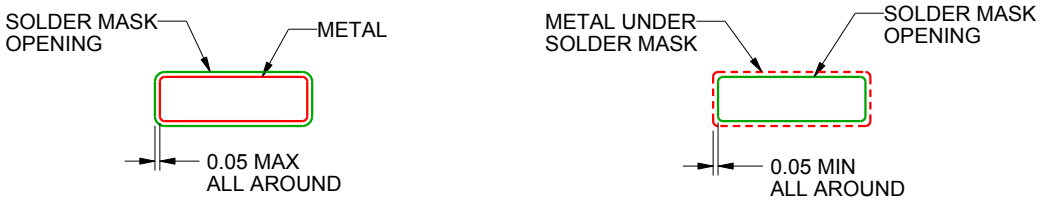


NOTES:

1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.
2. This drawing is subject to change without notice.
3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0.15 mm per side.
4. This dimension does not include interlead flash. Interlead flash shall not exceed 0.25 mm per side.
5. Reference JEDEC registration MO-153, variation AA.



LAND PATTERN EXAMPLE
SCALE:10X

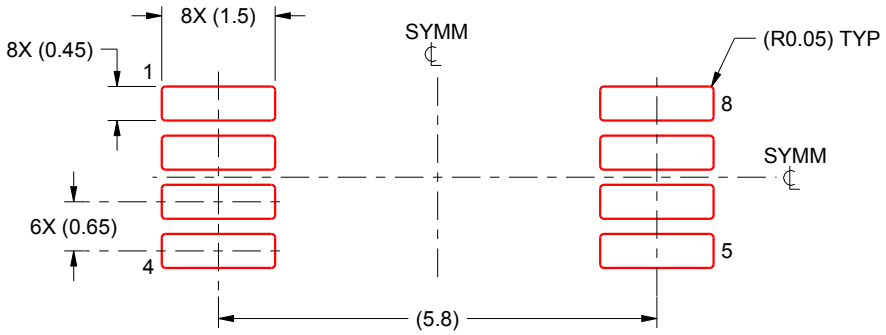


SOLDER MASK DETAILS
NOT TO SCALE

4221848/A 02/2015

NOTES: (continued)

6. Publication IPC-7351 may have alternate designs.
7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.



SOLDER PASTE EXAMPLE
BASED ON 0.125 mm THICK STENCIL
SCALE:10X

4221848/A 02/2015

NOTES: (continued)

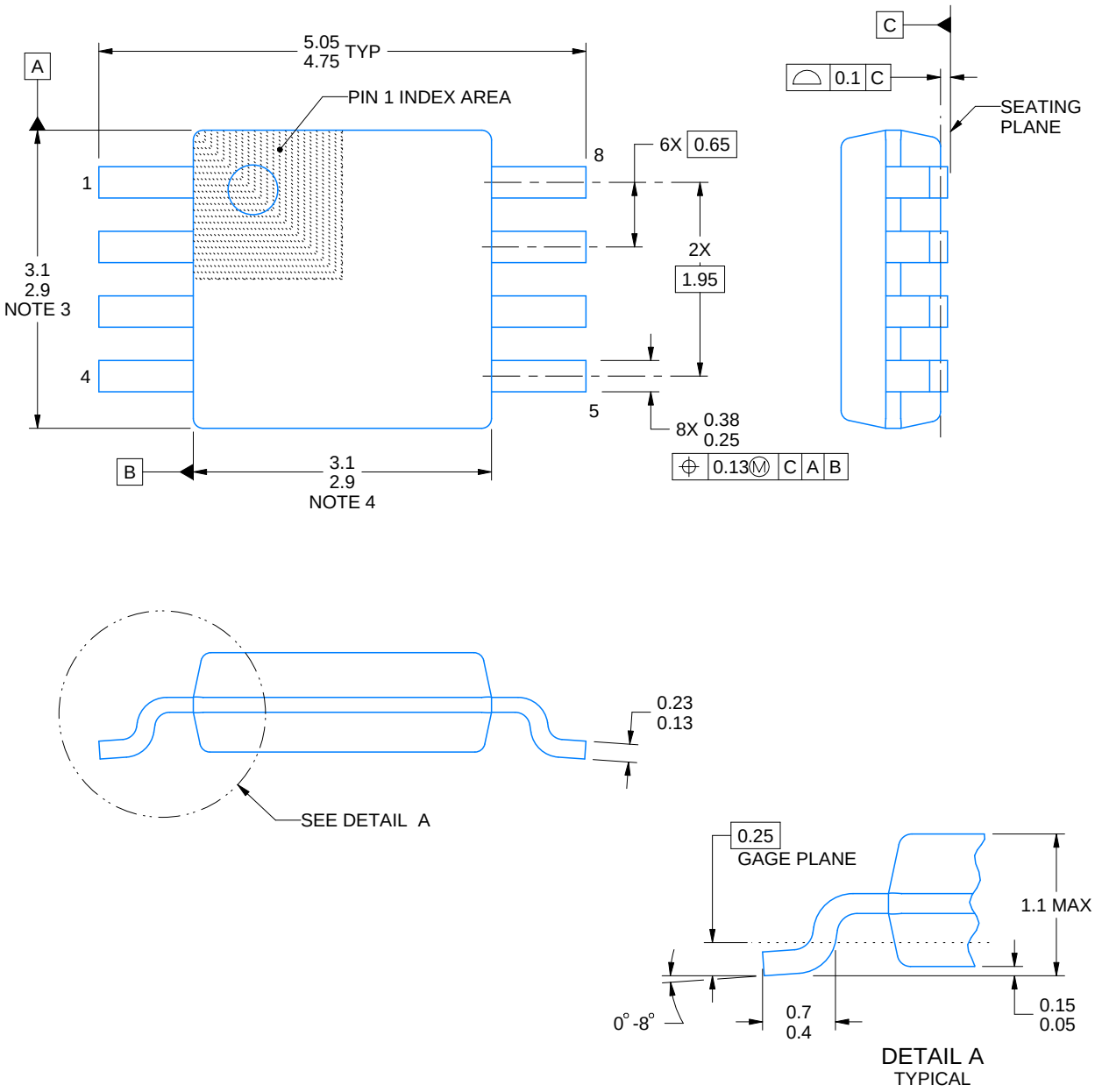
8. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
9. Board assembly site may have different recommendations for stencil design.

PACKAGE OUTLINE

DGK0008A

VSSOP - 1.1 mm max height

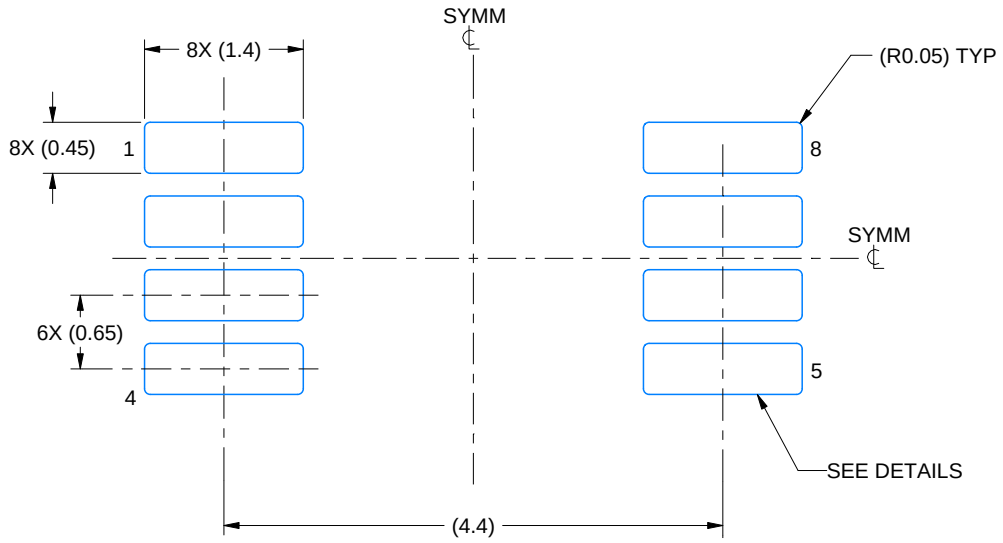
SMALL OUTLINE PACKAGE



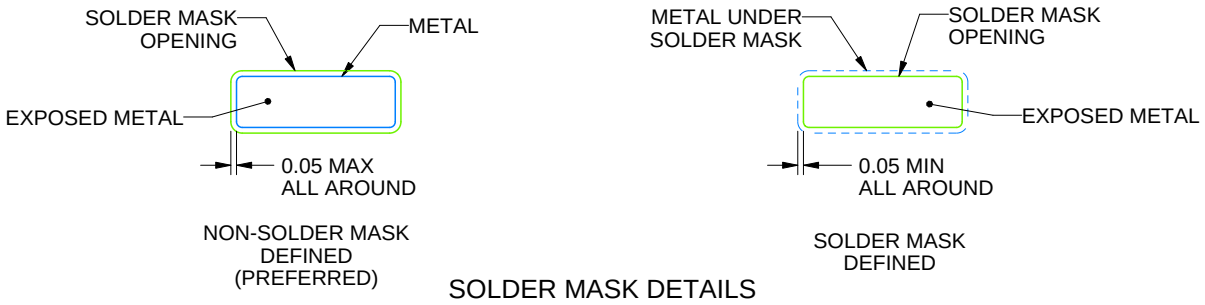
PowerPAD is a trademark of Texas Instruments.

NOTES:

1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.
2. This drawing is subject to change without notice.
3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0.15 mm per side.
4. This dimension does not include interlead flash. Interlead flash shall not exceed 0.25 mm per side.
5. Reference JEDEC registration MO-187.



LAND PATTERN EXAMPLE
EXPOSED METAL SHOWN
SCALE: 15X

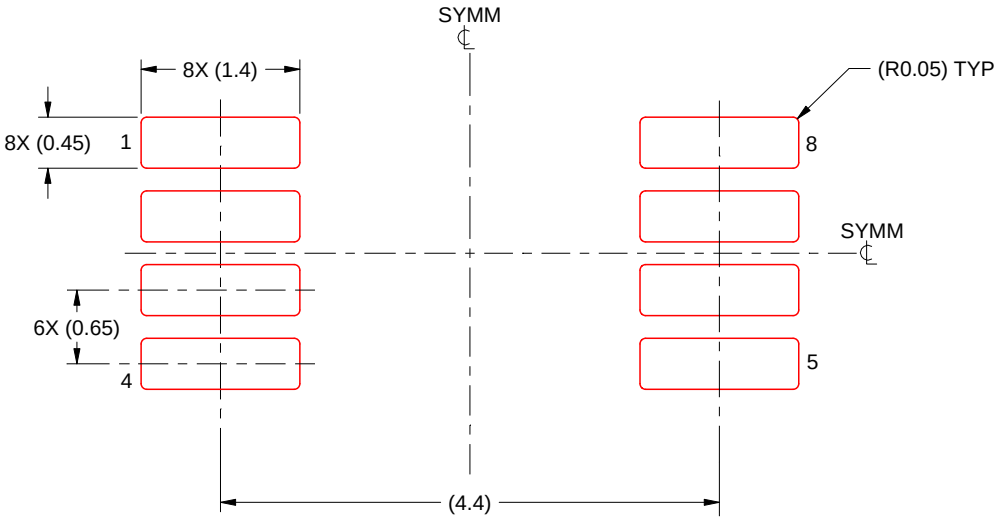


SOLDER MASK DETAILS

4214862/A 04/2023

NOTES: (continued)

6. Publication IPC-7351 may have alternate designs.
7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.
8. Vias are optional depending on application, refer to device data sheet. If any vias are implemented, refer to their locations shown on this view. It is recommended that vias under paste be filled, plugged or tented.
9. Size of metal pad may vary due to creepage requirement.



SOLDER PASTE EXAMPLE
SCALE: 15X

4214862/A 04/2023

NOTES: (continued)

11. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
12. Board assembly site may have different recommendations for stencil design.

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